# COM

## SERVICE MANUAL

144MHz FM TRANSCEIVER

IC-2100H IC-2100-T

Icom Inc.

### INTRODUCTION

This service manual describes the latest service information for the IC-2100H/IC-2100-T 144 MHz FM TRANSCEIVER at the time of publication.

MODEL	VERSION	SYMBOL	
	Europe	EUR	
	Europe Italy Taiwan U.S.A Asia Latin America	ITA	
10 040011	Taiwan	TPE	
IC-2100H	U.S.A	USA	
	Asia	SEA	
	Latin America	LA	
IC-2100-T	Thailand	THA	

To upgrade quality, any electrical or mechanical parts and internal circuits are subject to chang without notice or obligation

### DANGER

**NEVER** connect the transceiver to an AC outlet or to a DC power supply that uses more than 16 V. This will ruin the transceiver.

DO NOT expose the transceiver to rain, snow or any liquids.

**DO NOT** reverse the polarities of the power supply when connecting the transceiver.

**DO NOT** apply an RF signal of more than 20 dBm (100mW) to the antenna connector. This could damage the transceiver's front end.



### ORDERING PARTS

Be sure to include the following four points when ordering replacement parts:

- 1. 10-digit order numbers
- 2. Component part number and name
- 3. Equipment model name and unit name
- 4. Quantity required

#### <SAMPLE ORDER>

1110002550 IC TA725AP IC-2100H MAIN UNIT 5 pieces 8810008660 Screw PH BO M3x8 NI IC-2100H Chassis 10 pieces

Addresses are provided on the inside back cover for your convenience.

#### REPAIR NOTES

- Make sure a problem is internal before disassembling the transceiver.
- DO NOT open the transceiver until the transceiver is disconnected from its power source.
- DO NOT force any of the variable components. Turn them slowly and smoothly.
- DO NOT short any circuits or electronic parts. An insulated turning tool MUST be used for all adjustments.
- DO NOT keep power ON for a long time when the transceiver is defective.
- DO NOT transmit power into a signal generator or a sweep generator.
- 7. ALWAYS connect a 50 dB to 60 dB attenuator between the transceiver and a deviation meter or spectrum analyzer when using such test equipment.
- 8. READ the instructions of test equipment thoroughly before connecting equipment to the transceiver.

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## SECTION 1 SPECIFICATIONS

#### **■ GENERAL**

- Frequency range

Version	Receive	Transmit
EUR, TPE, THA	144 000 - 146.000	144.000 – 146.000
ITA, SEA, LA	136.000 - 174.000°	136.000 - 174.000
USA	136.000 - 174.000°	140.000 - 150.000°

\*Specifications guaranteed 144.000 - 148.000 MHz only

Mode : FN

• Nomber of memory channel : 113 (Incl.3pairs of scan edges, 3 log, 3 repeater and 1 call channel)

Usable temperature range : -10°C to +60°C; +14°F to +140°F
 Frequency resolution : 5, 10, 12.5, 15, 20, 25, 30 and 50 kHz
 Frequency stability : ±10 ppm (-10°C to +60°C; +14°F to +140°F)

**Transmit** 

• Power supply requirement : 13.8 V DC ±15 % (negative ground)

• Current drain (at 13.8 V DC) : Receive Standby (squelched) 0.8 A

Max. audio 1.0 A at 55 W 12.0 A

at 25 W (TPE version) 7.0 A at 10 W (THA version) 5.5 A

Antenna connector : SO-239 (50 Ω)

• Dimensions : 140(W)×40(H)×180(D) mm; (projections not included) 51/2(W)×19/16(H)×73/52(D) inch

Weight : 1.2 kg; 2 lb 10 oz

#### **■ TRANSMITTER**

Output power

Version	High	Middle	Low
except TPE, THA	55 W	10 W	5 W
TPE	25 W	1 to 1	5 W
THA	10 W		5 W

Modulation system : Variable reactance frequency

Maximum frequency deviation: ±5.0/±2.5\* kHz
 \*Europe and Italy versions only
 Spurious emissions
 : Less than -60 (-55\*) dB
 \*Thailand version only

Microphone connector : 8-pin modular (600 Ω)

#### **■ RECEIVER**

Receive system : Double-conversion superheterodyne
 Intermediate frequency : 1st 15.65 MHz

2nd 450 kHz

Sensitivity (at 12 dB SINAD) : Loss than 0.18 μV
 Squelch sensitivity (threshold) : Less than 0.13 μV

Selectivity (wide/narrow)
 : More than 12/6\* kHz at -6 dB

Less than 28/18\* kHz at -60 dB

\*Europe and Italy versions only

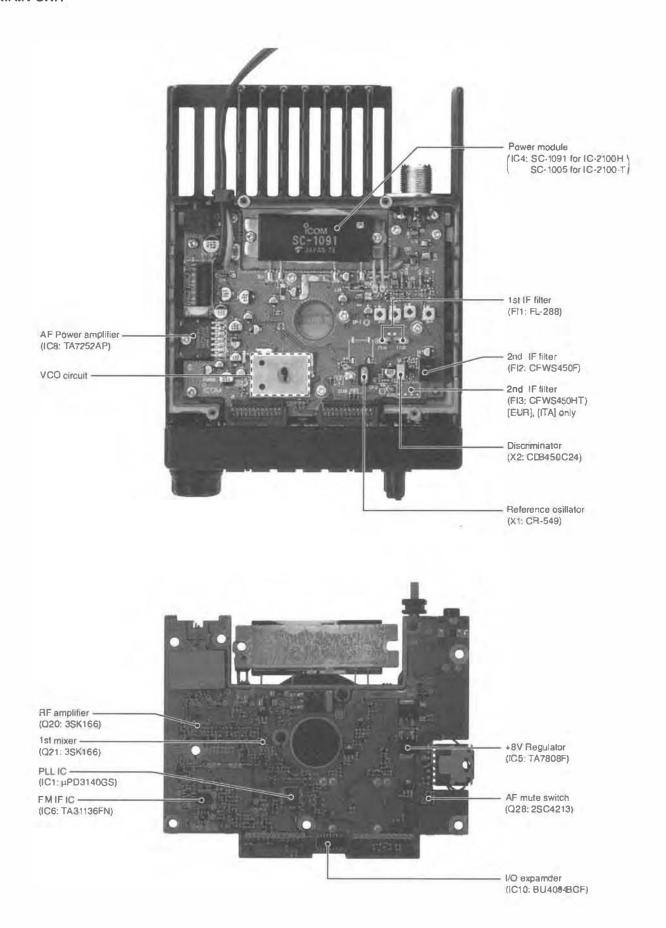
Spurious and image rejection; More than 60 dB
 Intermodulation rejection retio: More than 70 dB

• Audio output power (at 13.8 V) : More than 2.4 W at 10% distortion with an  $8\Omega$  load

External speaker connector : 3-conductor 3.5(d) mm (½\*)/8 Ω

## **SECTION 2** INSIDE VIEWS

## • MAIN UNIT



## SECTION 3 CIRCUIT DESCRIPTION

### **3-1 RECEIVER CIRCUITS**

### 3-1-1 ANTENNA SWITCHING CIRCUIT (MAIN unit)

The antenna switching circuit functions as a low-pass filter while receiving and a resonator circuit while transmitting. The circuit does not allow transmit signals to enter receiver circuits.

Received signals enter the antenna connector and pass through the low-pass filter (L17–L20, C55-C64). The filtered signals are passed through the  $\lambda/4$  type antenna switching circuit (D10, D11, I.22, L23) and are then applied to the RF amplifier (Q20).

#### 3-1-2 SQUELCH ATTENUATOR

The attenuator circuit attenuates the signal strength to a maximum of 10 dB to protect the RF amplifier from distortion when excessively strong signals are received.

The current flow of the antenna switching circuit (D10, D11) is controlled by the [SQL] control via the attenuator controller (IC7). When the [SQL] control is rotated clockwise deeper than 12 o'clock, the current of D10 and D11 is increased. In this case, D10 and D11 act as an attenuator.

### 3-1-3 RF CIRCUIT (MAIN unit)

The RF circuit amplifies signals within the range of frequency coverage and filters out-of-band signals.

The signals from the antenna switching circuit pass through the tunable bandpass filter (D13). The filtered signals are amplified at the RF amplifier (Q20) and then enter another three-stage bandpass filters (D14–D16) to suppress unwanted signals. The filtered signals are applied to the 1st mixer circuit (Q21).

The tunable bandpass filters (D13–D16) employ varactor diodes to tune the center frequency of the RF passband for wide bandwidth receiving and good image response rejection. These diodes are controlled by the PLL lock voltage via the tune control circuit (IC2, D4).

## 3-1-4 1ST MIXER AND 1ST IF CIRCUITS (MAIN unit)

The 1st mixer circuit converts the received signals to a fixed frequency of the 1st IF signal with the PLL output frequency. By changing the PLL frequency, only the desired frequency will pass through a pair of crystal filters at the next stage of the 1st mixer.

The RF signals from the bandpass filter are applied to the 1st mixer circuit (Q21). The applied signals are mixed with the 1st LO signal coming from the RX-VCO circuit (Q33, D23) to produce a 15.65 MHz 1st IF signal. The 1st IF signal passes through a pair of crystal filters (FI1a/b) to suppress out-of-band signals. The filtered signal is amplified at the 1st IF amplifier (Q22) and applied to the 2nd IF circuit

## 3-1-5 2ND IF AND DEMODULATOR CIRCUITS (MAIN unit)

The 2nd mixer circuit converts the 1st IF signal to a 2nd IF signal. A double-conversion superheterodyne system improves the Image rejection ratio and obtains stable receiver gain.

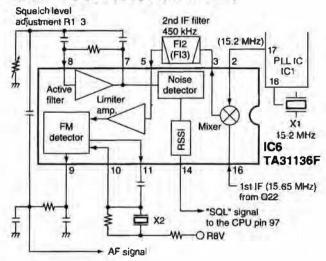
The 1st IF signal from the IF amplifier (Q22) is applied to the 2nd mixer section of the FM IF IC (IC6, pin 16) and is then mixed with the 2nd LO signal for conversion to a 450 kHz 2nd IF signal.

IC6 contains the 2nd mixer, limiter amplifier, quadrature detector, S-meter detector, active filter and noise amplifier circuits, etc. A frequency from the PLL reference oscillator is used for the 2nd LO signal (15.2 MHz).

The 2nd IF signal from the 2nd mixer (IC6, pin 3) passes through the ceramic filter (Fi2) (during wide channel spacing selection or passes through FI3 during narrow channel spacing selection; [EUR], [ITA] only). It is then amplified at the limiter amplifier section (IC6, pin 5) and applied to the quadrature detector section (IC6, pins 10, 11 and X2) to demodulate the 2nd IF signal into AF signals.

The AF signals are output from pin 9 (IC6) and are then applied to the AF amplifier circuit

#### • 2nd IF AND DEMODULATOR CIRCUITS



#### 3-1-6 AF CIRCUIT (MAIN unit)

The AF amplifier circuit amplifies the demodulated AF signals to drive a speaker.

The AF signals from IC6 (pin 9) are amplified at the active filters (Q23 HPF, Q24 LPF) and pass through the detector mute switch (Q25), and are level adjusted with the volume control on the LOGIC unit.

The AF amplifier IC8 amplifies the signals to a sufficient level to drive the speaker. The AF mute switch (Q28) turns ON to cut the signal to be input to the AF amplifier (IC8) during transmission.

## 3-1-7 SQUELCH CIRCUIT (MAIN and LOGIC units) • NOISE SQUELCH

The noise squelch circuit cuts out AF sig nals when no RF signals are received. By detecting noise components in the AF signals, the squelch circuit switches the AF mute switch.

A portion of the AF sig nals from the FM IF IC (IC6, pin 9) are applied to the active filter section (IC6, pin 8). The active filter section amplifies and filters noise components. The filtered sig nals are applied to the noise detector section and output from pin 14 as the "SQL" sig nal.

The "SQL" sig nal from IC6 (pin14) is applied to the CPU (LOGIC unit; IC1, pin 98). The CPU analyzes the noise condition and outputs the "RMUT" and "AMUT" sig nals via the I/O expander IC (LOGIC unit; IC10) to toggle the detector (Q25) and AF (Q28) mute switches.

Even when the squelch is closed, the AF mute switch (Q28) opens at the moment of emitting beep tones.

#### • TONE SQUELCH

The tone squelch circuit detects AF sig nals and opens the squelch only when receiving a sig nal containing a matching subaudible tone (CTCSS). When tone squelch is in use, and a sig nal with a mismatched or no subaudible tone is received, the tone squelch circuit mutes the AF sig nals even when noise squelch is open.

A portion of the AF sig nals from the FM IF IC (IC6, pin 9) passes through the low-pass filter (LOGIC unit; IC6) to remove AF (voice) signals and is applied to the CTCSS decoder inside the CPU (LOGIC unit; IC1, pin 1) via the "TONEIN" line to control the DET and AF mute switches.

## 3-2 TRANSMITTER CIRCUIT 3-2-1 MICROPHONE AMPLIFIED (LOGIC unit)

The microphone amplifier circuit amplifies audio signals with +6 dB/octave pre-emphasis characteristics from the microphone to a level needed for the modulation circuit.

The AF sig nals from the microphone are adjusted for impedance-matching at the MIC sensitivity control circuit (IC4, D4). The adjusted sig nals pass through the MIC mute switch (Q4), and are then amplified at the microphone amplifier (Q5) and the limiter amplifier (IC5a) which has a negative feedback circuit for +6 dB/octave pre-emphasis.

The amplified signals are applied to the tow-pass filter (IC5b) to filter out RF components and are then applied to the MAIN unit as the "MOD" signal.

#### 3-2-2 MODULATION CIRCUIT (MAIN unit)

The modulation circuit modulates the VCO oscillating signal (RF signal) using the microphone audio signals.

The audio sig nals (MOD) change the reactance of D1 to modulate the oscillated sig nal at the TX-VCO circuit (Q1, Q2). The modulated sig nal is amplified at the buffer amplifier (Q4) and LO amplifier (Q5), then applied to the drive amplifiers.

#### 3-2-3 DRIVE AMPLIFIER CIRCUIT (MAIN unit)

The drive amplifier circuit amplifies the VCO oscillating signal to the level needed at the power amplifier.

The RF sig nal from the LO amplifier (Q5) passes through the T/R switch (D5) and is amplified at the pre-drive (O13) and drive (Q14) amplifiers. The amplified signal is applied to the power amplifier circuit.

#### 3-2-4 POWER AMPLIFIER CIRCUIT (MAIN unit)

The power amplifier circuit amplifies the driver signal to an output power level.

The RF sig nal from the drive amplifier (Q14) is applied to the power module (IC4) to obtain 55 W (25 W for Taiwan version, 10 W for the IC-2100-T Thailand version) of RF power.

The amplified sig nals is passed through the antenna switching circuit (D7), APC detector circuit (L18, D8, D9), and low-pass filter (L19, L20, C62-C64) and is then applied to the antenna connector.

Collector voltages for the driver (Q13) and control voltage for the power amplifier (IC4, pin 2) are controlled by the APC circuit to protect the power module from a mismatched condition as well as to stabilize the output power.

#### 3-2-5 APC CIRCUIT (MAIN unit)

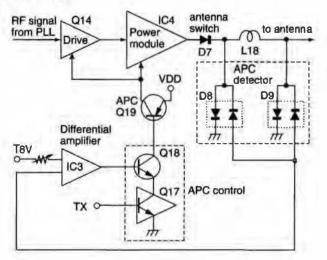
The APC circuit protects the power amplifier from a mismatched output load and stabilizes the output power.

The APC detector circuit (L10, D8, D9) detects forward signals and reflection signals at D8 and D9 respectively. The combined voltage is at minimum level when the antenna impedance is matched at 50  $\Omega$  and is increased when it is mismatched.

The detected voltage is applied to the differential amplifier (IC3, pin 3), and the power setting voltage is applied to the other input (pin 1) for the reference.

When antenna impedance is mismatched, the detected voltage exceeds the power setting voltage. The output voltage of the differential amplifier (IC3, pin 4) controls the input current of the power module (IC4) and drive amplifier (Q14) to reduce the output power via the APC controller (Q18, Q19).

#### APC circuit



## 3-3 PLL CIRCUITS 3-3-1 PLL CIRCUIT

A PLL circuit provides stable oscillation of the transmit frequency and the receive 1st LO frequency. The PLL circuit compares the phase of the divided VCO frequency to the reference frequency. The PLL output frequency is controlled by the divided ratio (N-data) of a programmable divider.

An oscillated sig nal from the VCO passes thorough the buffer amplifiers (Q4, Q6) is applied to the PLL IC (IC1, pin 2) and is prescaled in the PLL IC based on the divided ratio (N-data). The reference signal is generated at the reference oscillator (X1) and is also applied to the PLL IC. The PLL IC detects the out-of-step phase using the reference frequency and outputs it from pin 8. The output signal is passed thorough the toop filter (R89, R90, C105, C107) and is then applied to the VCO circuit as the lock voltage.

The lock voltage is also used for the receiver tunable bandpass filters to match the filter's center frequency to the desired receive frequency. The lock voltage is applied to the band pass filters (D13-D16) via the tune control circuit (IC4, D4).

### 3-3-2 VCO CIRCUIT (MAIN unit)

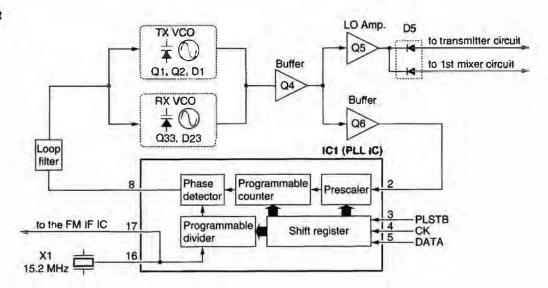
The VCO circuit contains a separate TX-VCO (Q1, Q2, D1) and RX-VCO (Q33, D23). The oscillated sig nal is amplified at the buffer (Q4) and LO (Q5) amplifiers, and is then applied to the T/R switching circuit (D5). Then the Tx and Rx sig nals are applied to the pre-driver (Q13) and 1st mixer (Q21) respectively.

A portion of the signal from Q4 is amplified at the buffer amplifier (Q6) and is then fed back to the PLL IC (IC1 pin 2) as the comparison signal.

## 3-4 POWER SUPPLY CIRCUITS VOLTAGE LINES

Line	Description
HV	The voltage from the connected DC power supply.
13.8V	The same voltage as the HV line which is controlled by the power switching circuit (Q25, Q26, Q35). When the [POWEA] switch is pushed, the CPU outputs the "PWRON" control signal to the power switching circuit to turn the circuit ON.
C5 V	Common 5 V for the CPU converted from the HV line by the C5V regulator circuit (IC9). The circuit outputs the voltage regardless of the power ON/OFF condition.
+8V	Common 8 V converted from the 13.8V line by the +8V regulator circuit (IC5).
R8V	Receive 8 V controlled by the R8V regulator circuit (Q29, Q30) using the "RX" signal from the I/O expander IC (IC10).
T8V	Transmit 8 V controlled by the T8V regulator circuit (Q11, Q12) using the "TX" sig nal from the I/O expand er IC (IC10).
+5V	Common 5 V converted from the +8V line by the +5 V regulator circuit (Q31, Q32).

### PLL circuit



## 3-5 PORT ALLOCATIONS 3-5-1 CPU (LOGIC UNIT IC1)

Pin number	Port name	Description
1	TON EIN	nput port for the CTCSS decode signals.
9	RES	Input port for the reset sig nal.
11	СК	Outputs clock signal to the VC expander ICs (IC10, MAIN unit; IC10) PLL IC (MAIN unit; IC1), etc.
12	DATA	Outputs data signals to the VC expander ICs (IC10, MAIN unit; IC10) PLL IC (MAIN unit; IC1), etc.
13	ESCK	Outputs clock signal to the EEPRON (IC7).
14	ESDA	VO port for the EEPROM (IC7) data signals.
16	RD	Input port for the cloning signal.
17	TD	Output port for the cloning sig nal.
18	PWRSW	Input for the POWER switch.  Low: While POWER switch is pushed.
19, 20	DLCK, DLUD	Input ports for up/down sig nals from main dial.
22	EXSTB	Outputs strobe signals for the VC expander ICs (IC10, MAIN unit; IC10)
23	MICIN	Input port for microphone serial signal via the buffer amplifier.
24	PLSTB	Outputs strobe sig nals for the PLL IC (MAIN unit; IC1).
25	E-TONE	Outputs 1750 Hz Europe tone signal.
26	UNLK	Input port for PLL unlock signal from the PLL IC (MAIN unit; IC1). High: During unlock
33-35	COM3- COM1	Output LCD drive signals.
3 <del>6</del> –39	KRO- KR3	Input ports for initial matrix.
40	PWRON	Outputs power switching circuit con trol sig nal.  High: While turning power ON.
41	COLOR	Outputs color control sig nal for display backlight. High: While display backlight is amber.
42, 43	DIMO, DIM1	Outputs brig htness control sig nal for display back lig ht.
44-75	SEG9- SEG40	Output LCD drive signals.
77-88	SEG41- SEG52	Capat Los dilve signals.
90	CTCSS	Outputs CTCSS signals.
91	DTMF	Outputs DTMF signals.

Pin number	Port name	Description			
93	PTT	Input port for the PTT switch. High: While PTT switch is pushed.			
94	EXTMIC	Input port to detect remote microphor connection.  Low: HM-90/98 is connected.			
96 SQLV		Input port for squelch setting level signal.			
97	SQL	Input port for squelch level signal.			
99	SMET	Input port S-meter level signal.			
100	MICUD	Input ports for up/down sig nals from a microphone.			

## 3-5-2 I/O expander IC (1) IC10 (LOGIC unit)

Pin number	Port name	Description			
11	W/N	Outputs receive/transmit passband width control signal.  High: While narrow bandwidth is selected. ([EUR], [ITA] only)			
12	MMUTE	Outputs MIC mute control signal.  High: While DTMF signals are output, etc.			
13	AMUTE	Outputs AF mute switch (MAIN unit; Q28) control sig nal. High: While squelched.			
14	RMUTE	Outputs detector mute switch (MAIN unit; Q25) control sig nal.  High: While squelched.			

## (2) IC10 (MAIN unit)

Pin number	Port name		Description					
4	TX	Outputs the T8V regulator (Q11 control signal.  Low: While transmitting						
7		Output	RF power	control si	gnals.			
	LP1, LP2			RF power				
5, 6			High	Mid	Low			
7540		LP1	L	L	н			
		LP2	L	Н	L			
7	SHIFT	Outputs TX-VCO/RX-VCO select signal. High: While transmitting Outputs the R8V regulator (Q29, Q30) control signal. Low: While receiving						
14	RX							

## SECTION 4 ADJUSTMENT PROCEDURES

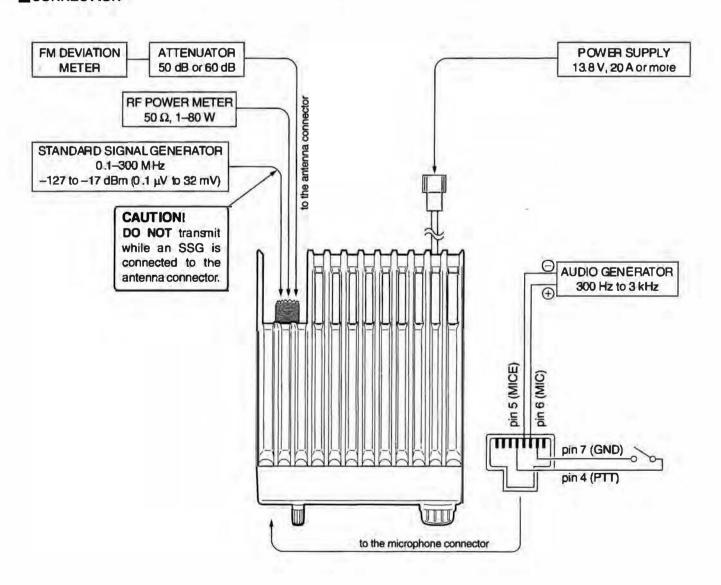
### **4-1 PREPARATION**

All adjustments in this section must be performed on wide bandwidth condition unless specified otherwise. (Narrow bandwidth is selectable for Europe and Italy vertions only.)

#### **TREQUIRED TEST EQUIPMENT**

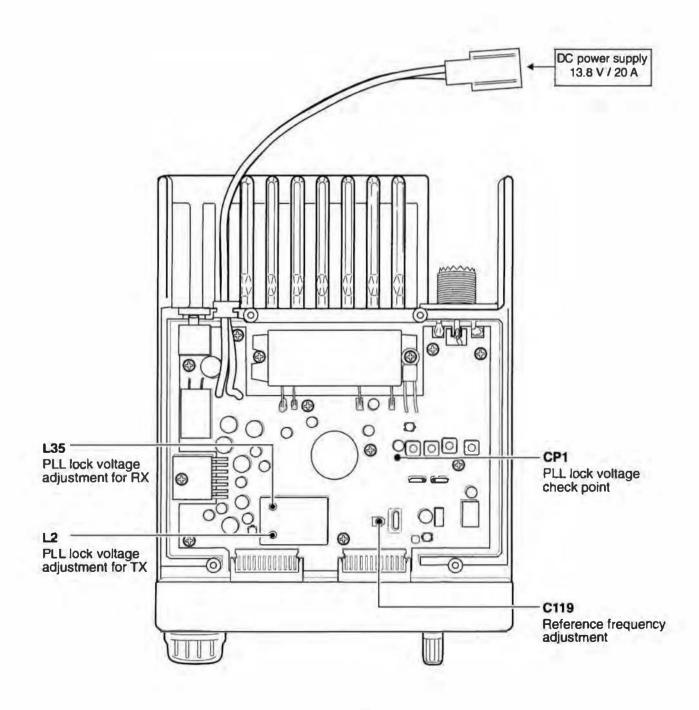
EQUIPMENT	GRADE	AND RANGE	EQUIPMENT	GRADE	AND RANGE
DC power supply	7	: 13.8 V DC : 20 A or more	Audio generator	Frequency range Measuring range	: 300-3000 Hz : 1-500 mV
RF power meter (terminated type)	Frequency range Impedance	: 180 W : 100300 MHz : 50 Ω	Standard signal generator (SSG)	Frequency range Output level	; 0.1–300 MHz : 0.1 µV–32 mV (–127 to –17 dBm)
		: Less than 1.2 : 1 : 0.1–300 MHz	Oscilloscope	Frequency range Measuring range	: DC20 MHz : 0.0120 V
Frequency counter	Frequency accuracy Sensitivity	: ±1 ppm or better : 100 mV or better	AC millivoltmeter	Measuring range	: 10 mV-10 V
FM deviation meter		: 30-300 MHz : 0 to ±10 kHz	External speaker	Input impedance Capacity	: 8 Ω : 4 W or more
DC voltmeter		: 50 kQ/V DC or better	Attenuator	Power attenuation Capacity	: 50 or 60 dB : 100 W or more

#### **CONNECTION**



## **4-2 PLL ADJUSTMENTS**

ADJUSTMENT		ADJUSTMENT CONDITION MEASUREMENT		MEASUREMENT			TMENT
			UNIT	LOCATION		UNIT	ADJUST
PLL LOCK VOLTAGE	1	Displayed frequency :     145.000 MHz     Receiving	MAIN	Connect a digital multi-meter or oscilloscope to the check point CP1.	1.25-1.30 V	MAIN	L35
	2	Transmitting			1.45-1.55 V		L2
PLL REFERENCE FREQUENCY	1	Displayed frequency:     145.000 MHz [EUR, TPE, THA]     146.000 MHz [ITA, USA, SEA, LA]     Output power: Low     Transmitting	Rear Panel	Loosely couple the frequency counter to the antenna connector.		MAIN	C119

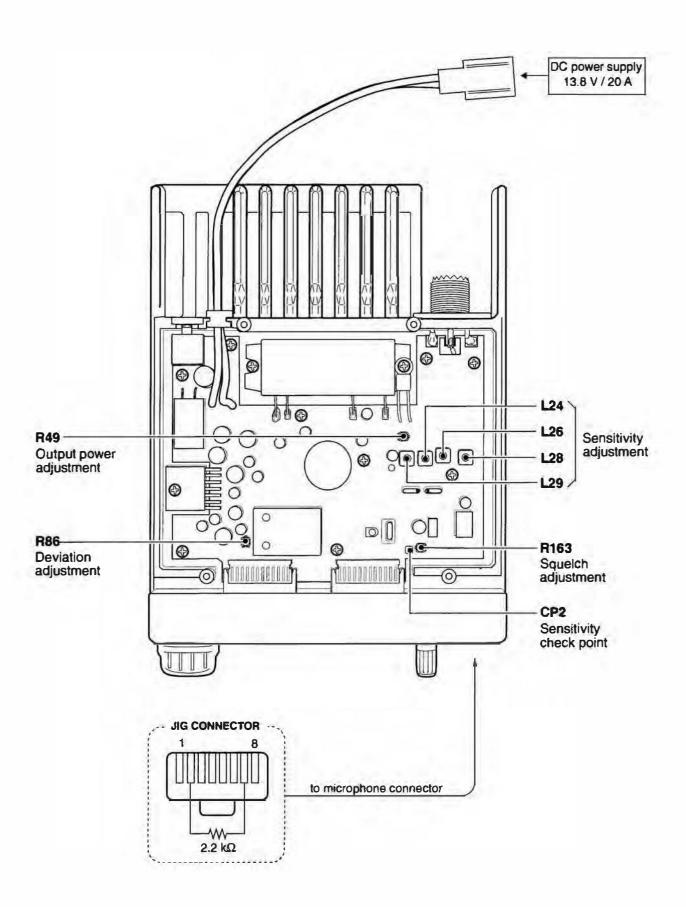


## 4-3 TRANSMITTER AND RECEIVER ADJUSTMENTS

The receiver adjustments must be performed after PLL ADJUSTMENTS.

ADJUSTME	NT	ADJUSTMENT CONDITION	M	EASUREMENT	VALUE	ADJUSTMENT POINT	
A.5000111121	•		UNIT LOCATION			UNIT	ADJUS1
OUTPUT POWER	1	Displayed frequency:     145.000 MHz [EUR, TPE, THA]     146.000 MHz [ITA, USA, SEA, LA]     Output power : High     Transmitting	Rear Panel	Connect the RF power meter to the antenna connector.	25 W [TPE]	MAIN	R49
FM DEVIATION	1	Displayed frequency: 145.000 MHz [EUR, TPE, THA] 146.000 MHz [ITA, USA, SEA, LA]  Output power : Low Connect an audio generator to the [MIC] connector and set as: 1 kHz/ 50 mV [USA] 1 kHz/ 20 mV [other]  TONE : OFF Set an FM deviation meter as: HPF: 50 Hz LPF: 20 kHz De-emphasis: OFF Detector : (P-P)/2  Transmitting	Rear Panel	Connect an FM deviation meter to the antenna connector through an attenuator.	±4.8 kHz	MAIN	R86
	2	IF bandwidth : Narrow			±2.0-±3.0 kHz		Verify
SENSITIVITY	1	Displayed frequency:  145.000 MHz [EUR, TPE, THA]  146.000 MHz [ITA, USA, SEA, LA]  Connect an SSG to the antenna connector and set as:  Level: 32 μV*  (-77 dBm)  Deviation: ±3.5 kHz  Modulation: 1 kHz  Receiving	MAIN	Connect a digital multimeter or oscilloscope to check point CP2.	Maximum voltage	MAIN	Adjust in sequence repeated- iy. L24, L26, L28, L29
SQUELCH/ S-METER (SQUELCH)	1	Turn into squelch/S-meter setting mode. Connect a JIG to the [MIC] connector, then turn power ON. Displayed frequency: 145.000 MHz [EUR, TPE, THA] 146.000 MHz [ITA, USA, SEA, LA] R163: Max. clockwise Connect an SSG to the antenna connector and set as: Level: 0.071 μV* (-130 dBm) Deviation: \$3,5 kHz Modulation: 1 kHz Receiving	Speaker		At the point where the signal just appears.	MAIN	R163
(S-METER)	2	• Set an SSG as :  Level : 1.0 µV*  (-107 dBm)  Deviation : ±3.5 kHz  Modulation : 1 kHz • Receiving	Display	S/RF indicator	Push and hold the [S.MW] key, or pus the [MW] key on the HM-98.  • Verify that S-meter shows S3 (4 do		

<sup>\*</sup>This output level of the standard signal generator (SSG) is indicated as SSG's open circuit.



## SECTION 5 PARTS LIST

## [LOGIC UNIT]

REF NO.	ORDER NO.		DESCRIPTION
IC1	114 000 7020		H06433875A83H [THA] only
	1140007420	2 1.43	HD6433875A85H other
IC2	1110002860		TA75S393F (TE85R)
IC4	1130004200		TC4S66F (TE85R)
IC5	1110000960		NJM4558M(T1)
IC6	1110000960		NJM4558M(T1)
IC7	1130007290		24LC168T-I/SN
IC8	1110004750		S-80945ALMP-DA9-T2
IC10	1130007700	S.IC	BU4094BCF-T1
Q1	1530002060	S.TRANSISTOR	2SC4081 T107 R
Q2	1590001330	S.TRANSISTOR	DTA114EUA T106
Q3	1540000250	S.TRANSISTOR	2SD999-T2 CK
Q4	1590001390	S.FET	2SJ144-Y (TE85R)
Q5	1530002060	S.TRANSISTOR	2SC4081 T107 R
Q6	1530002060	S.TRANSISTOR	2SC4081 T107 R
Q7	1590001390		2SJ144-Y (TE85R)
Q8		S.TRANSISTOR	DTC144EUAT106
Q11		S.TRANSISTOR	DTC144TU T107
Q18	1590000430	S.TRANSISTOR	DTC144EUA T106
Q20	1530002B50	S.TRANSISTOR	2SC4116-BL(TE85R) [EUR], (ITA) only
Q21	1530002060	S.TRANSISTOR	2SC4081 T107 FI
Q22		S.TRANSISTOR	2SC4081 T107 FI
Q23		S.TRANSISTOR	2SC4081 T107 FI
Q24		S.TRANSISTOR	2SC4081 T107 R
Q25		S.TRANSISTOR	2SC4081 T107 FI
Q26		S.TRANSISTOR	DTC144EUA T106
027		S.TRANSISTOR	2SA1576AT106 R
Q28		S.TRANSISTOR	DTC144EUA T106
D1	1720002280	S.ZENER	MA8091-M (TX)
D1	The second secon	C	MA8091-M (TX)
D2 D3	1730002280 1750000550		1SS355 TE-17
D3	1750000550		1SS355 TE-17
D5	1750000550		1SS355 TE-17
D6	1730002280	E 4 A 4. LUC	MA8091-M (TX)
D7	1750000550	THE RESERVE OF THE PARTY OF THE	1SS355 TE-17
D9	1750000130		DA204U T107
D12	1160000060		DAN202U T107
D13	1160000060		DAN202U T107
D14	1160000060	1.7	DAN202UT107
D15	1750000550		1SS355 TE-17
D16	1710000600		1SS254 [EUR], [TPE]
D18	1750000550		1SS355 TE-17
DIO	1730000330	3.DIODE	[EUR], [TPE], [USA]
D19	1750000550	SDIODE	1SS355 TE-17 [THA]
4	1160000060		DAN202IJ T107 [EUR]
D21	1750000170		DA115 T107
	1730000170	U.DIODE	[TPE], [THA]
	1750000160	SDIODE	DA114 T107 [SEA]
D22	1750000170		DA115 T107 {ITA}
	1750000160		DA114 T107 [TPE]
D23	1160000060		DAN202U T107
D23	1750000550		1SS355 TE-17
D25	1750000550		1SS355 TE-17
Х1	6050009600	S.XTAL	SMD-49 (8.000 MHz)
	ennoncoro	6 0011	LOW an appared (Coo)
L1	6200005950		LQH 3N 2R2M04 (Q20)
12	6200004920	S.COIL	MLF1608A 2R2K-T
L3	6200004920		MLF1608A 2R2K-T
L4	6200004920		MLF1608A 2R2K-T
L5	6200005950		LOH 3N 2R2M04 (Q20)
L6	6200004920		MLF1608A 2R2K-T MLF2012D R82K-T
L7 LB	6200001520 6200004920		MLF2012D H82K-{ MLF1608A 2F2K-T
	3200004020		
R1		S.RESISTOR	ERJ3GEYJ 223 V (22 kΩ)
	7020002560	S.RESISTOR	ERJ3GEYJ 103 V (10 №2)
R2 R3			ERJ3GEYJ 222 V (2.2 kΩ)

## [LOGIC UNIT]

REF NO.	ORDER NO.		DESCRIPTION
R4		S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)
R5		S.RESISTOR	
R6	The second second	S.RESISTOR	MCR50JZHJ 18 Ω (180)
A7		S.RESISTOR	MCR10EZHJ 1 Ω (010)
R8		S.RESISTOR	ERJ3GEYJ 124 V (120 kΩ)
A9		S.RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)
H10		S.AESISTOR	ERJ3GEYJ 394 V (390 kΩ)
R11		S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R12		S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ) ERJ3GEYJ 104 V (100 kΩ)
R13		S.RESISTOR S.RESISTOR	the state of the s
R14		S.RESISTOR	ERJ3GEYJ 122 V (1.2 kΩ) ERJ3GEYJ 101 V (100 Ω)
R15	7030003320	S.RESISTOR	the state of the s
A17		S.RESISTOR	ERJ3GEYJ 223 V (22 kΩ)
		S.RESISTOR	
A18		S.RESISTOR	ERJ3GEYJ 392 V (3.9 kΩ)
A19	7030003560	THE RESERVE OF THE PARTY OF THE	ERJ3GEYJ 103 V (10 kΩ)
R20	1000	S.RESISTOR	ERJ3GEYJ 562 V (5.6 kΩ) [TPE], (USA] only
R21		S.RESISTOR	
R22		S.RESISTOR	
R23		S.RESISTOR	ERJ3GEYJ 223 V (22 kΩ)
R24		S.RESISTOR	ERJ3GEYJ 470 V (47 Ω)
R25		S.RESISTOR	ERJ3GEYJ 681 V (680 Ω)
R28	CONTRACTOR OF THE PARTY OF THE	S.RESISTOR	ERJ3GEYJ 101 V (100 Ω)
R27		S.RESISTOR	ERJ3GEYJ 331 V (330 Ω)
R28		S.RESISTOR	ERJ3GEYJ 474 V (470 kΩ)
R29		S.RESISTOR	ER/3GEYJ 104 V (100 kΩ)
R30		S.RESISTOR	ERJ3GEYJ 473 V (47 KΩ)
R31		S.AESISTOR S.AESISTOR	ER./3GEYJ 274 V (270 kΩ) ER./3GEYJ 222 V (2.2 kΩ)
R32		S.RESISTOR	ERJ3GEYJ 105 V (1 MΩ)
H33		S.RESISTOR	ERJ3GEYJ 103 V (1 MΩ)
H34		S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R36		S.RESISTOR	ERJ3GEYJ 154 V (150 kΩ)
H37		S.RESISTOR	ERJ3GEYJ 391 V (390 Ω)
H36		S.RESISTOR	ERJ3GEYJ 824 V (820 kΩ)
R39		S.RESISTOR	ERJ3GEYJ 394 V (390 kΩ)
R40		S.RESISTOR	ERJ3GEYJ 824 V (820 kΩ)
R41		S.RESISTOR	ERJ3GEYJ 183 V (18 kΩ)
R42		S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
F143		S.AESISTOA	ERJ3GEYJ 123 V (12 kΩ)
R44		S.RESISTOR	ERJ3GEYJ 393 V (39 kΩ)
R45		S.RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)
R46		S.RESISTOR	ERJ3GEYJ 224 V (220 kΩ)
<b>F</b> 147		S.RESISTOR	ERJ3GEYJ 823 V (82 kΩ)
R48		S.RESISTOR	ERJ3GEYJ 823 V (82 kΩ)
R49		S.RESISTOR	ERJ3GEYJ 823 V (82 kΩ)
R50		S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
A51		S.RESISTOR	ERJ3GEYJ 474 V (470 kΩ)
R52		S.RESISTOR	ERJ3GEYJ 105 V (1 MΩ)
R53		S.RESISTOR	ERJ3GEYJ 823 V (82 kΩ)
R54		S.RESISTOR	ERJ3GEYJ 823 V (82 kΩ)
A55	The second second	S.RESISTOR S.RESISTOR	ERI3GEYJ 823 V (82 kΩ) ERJ3GEYJ 124 V (120 kΩ)
R56		S.RESISTOR	ER.I3GEYJ 474 V (470 kΩ)
R57 R58		S.AESISTOR	ERJ3GEYJ 104 V (100 kΩ)
R59		S.RESISTOR	ERJ3GEYJ 105 V (1 MΩ)
R60		S.RESISTOR	ER.I3GEYJ 474 V (470 kΩ)
R61	7210001870		EVU-F2AF20 A14 (10KA)
R62	7210001860		EVU-F2AF20 814 (10KB)
R64		S.RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)
R65		S.RESISTOR	ERJ3GEYJ 473 V (47 kΩ)
R66		S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R67		S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
<b>P68</b>		S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R69	7030003440	S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
A70		S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R71		S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
A73		S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
<b>F74</b>		S.RESISTOR	ERJ3GEYJ 105 V (1 MΩ)
A75		S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
A76		S.AESISTOR	ERJ3GEYJ 102 V (1 kΩ)
	7030003440	S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
A77		S.RESISTOR	ER.I3GEYJ 102 V (1 kΩ)

## [LOGIC UNIT]

REF NO.	ORDER NO.		DESCRIPTION
R79	7030003440		ERJ3GEYJ 102 V (1 kΩ)
R80	7030003440	S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R82	7030003560		ERJ3GEYJ 103 V (10 kΩ)
R83	7030003440 7030003560	S.RESISTOR S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ) ERJ3GEYJ 103 V (10 kΩ)
R93	7030003560		ERJ3GEYJ 102 V (1 kΩ)
R94	7030003440	COLUMN TAXABLE AT BUY.	ERJ3GEYJ 102 V (1 kΩ)
R95		SAESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R96	7030003440		ERJ3GEYJ 102 V (1 kΩ)
R97	7030003440		ERJ3GEYJ 102 V (1 kΩ)
R98	7030003440	S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R99	7030003440		ERJ3GEYJ 102 V (1 kΩ)
R100	7030003440		ERJ3GEYJ 102 V (1 kΩ)
R104	7030003580		ERJ3GEYJ 153 V (15 K2)
R124	7030003770	S.RESISTOR S.RESISTOR	ERJ3GEYJ 564 V (560 kΩ) ERJ3GEYJ 101 V (100 Ω)
R125	7030003320 7030003440	S.RESISTOR	ERJ3GEYJ 102 V (1 k\Q)
R133	7030003550		ERJ3GEYJ 822 V (8.2 kΩ)
11133	7000000000	0.1120101011	[EUR], [ITA] only
R134	7030003760	S.RESISTOR	ERJ3GEYJ 474 V (470 kΩ)
1476	J W		[EUR], (ITA) only
R135	7030003640	S.RESISTOR	ERJ3GEYJ 473 V(47 kΩ)
		1	[EUR], [ITA] only
R136	7030003560	S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R137	7030003560		ERJ3GEYJ 103 V (10 kΩ)
R138	7030003560	S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R143	7030003600	S.RESISTOR	ERJ3GEYJ 223 V (22 kΩ)
R144	7030003600		ERJ3GEYJ 223 V (22 kΩ) ERJ3GEYJ 102 V (1 kΩ)
R145	7030003440 7030003680	S.RESISTOR S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)
R149	7030003680	. 21 . 22.2 / // // /	ERJ3GEYJ 822 V (8.2 k(2)
R150	7030003550	Contract to the second	ERJ3GEYJ 822 V (8.2 kΩ)
R151	7030003550		ERJ3GEYJ 822 V (8.2 kΩ)
R152	7030003640	S.RESISTOR	ERJ3GEYJ 473 V (47 kQ)
R153	7030003520		ERJ3GEYJ 472 V (4.7 kΩ)
R154	7030003530	A	ERJ3GEYJ 562 V (5.6 kΩ)
R155	7030003320	S,RESISTOR	ERJ3GEYJ 101 V (100 Ω)
R156	7030003300	S.RESISTOR	ERJ3GEYJ 680 V (88 Ω)
R157	7030003340	S.RESISTOR	ERJ3GEYJ 151 V (150Ω)
R158	7030003410	S.RESISTOR	ERJ3GEYJ 561 V (560 Ω)
R159	7030003460	S.RESISTOR	ERJ3GEYJ 152 V (1.5 kΩ)
R160	7030003320		ERJ3GEYJ 101 V (100 Ω)
R181	7030003340	S.RESISTOR	ERJ3GEYJ 151 V (150 Ω) ERJ3GEYJ 271 V (270 Ω)
R162 R163	7030003370 7030003560	S.RESISTOR S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
C1	4030008860	S.CERAMIC	C1608 JB 1H 102K-T-A
C2		S.CERAMIC	C1608 JB 1H 102K-T-A
C3	40-40	S.CERAMIC	C1808 JB 1H 102K-T-A
C4		S.CERAMIC	C1808 JB 1H 102K-T-A
C5	4030008860	A CALL SALE	C1608JB 1H 102K-T-A
C6	4030007090	S.CERAMIC	C1608 CH 1H 470J-T-A
C7	4030008630	S.CERAMIC	C1808 JF 1C 104Z-T-A
C8	4510004630	THE RESERVE THE PARTY OF THE PA	
C9	4030006900	the state of the second st	C1608JB 1E 103K-T-A
C10	4510004830		
C11	4030008680		C2012 JF 1C 105Z-T-A C1608 JF 1C 104Z-T-A
C13	4030006860		C1608 JB 1H 102K-T-A
C14	4510004630	the state of the s	
C15	4030008900		C1608 JB 1C 333K-T-A
C16	4030007020		C1608 CH 1H 120J-T-A
C17	4030008680	S.CERAMIC	G2012 JF 1 C 105Z-T-A
C18	4030009490	S.CERAMIC	C1608 JB 1H 821 K-T-A
C19		S.CERAMIC	C1608JB 1H 272K-T-A
C20	7 1 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2	S.CERAMIC	C1608 CH 1H 8201-T-A
C21	4030007130		C1808 CH 1H 101J-T-A
C22	4030006860		C1808 JB 1H 102K-T-A
C23	4030008630		C1808 JF 1 C 104Z-T-A ECEV1CA100SR
C24 C25	4510004630 4030008630	THE RESERVE OF THE PARTY OF THE	C1608 JF 1C 104Z-T-A
C25	4030008630		C1808 JF 1 C 104Z-T-A
C27	4030008630		C1608 JF 1 C 104Z-T-A
C30	4030008630		C1608 JF 1 C 104Z-T-A
C31	4030008680		C2012 JF 1C 105Z-T-A
C32	4030006860		C1608 JB 1H 102K-T-A
C33	4030008630	S.CERAMIC	C1608 JF 1C 104Z-T-A
C34	4030006860		C1808 JB 1H 102K-T-A
C35	4030008630		C1608 JF 1C 104Z-T-A
C36	4030008910		C1608 JB 1 C 393K-T-A
C37	4030008630	S.CERAMIC	C1608 JF 1 C 104Z-T-A

## [LOGIC UNIT]

[LOGIC UNIT]				
REF NO.	ORDER NO.	DESCRIPTION		
C38	4030009980	S.CERAMIC	C1608 JB 1H 152K-T-A	
C39		- 1.55	C1608 JF 1C 104Z-T-A	
C40		S.CERAMIC	C1608 JF 1C 104Z-T-A C1608 JB 1E 103K-T-A	
C41 C42		S.CERAMIC S.CERAMIC	C1608 CH 1H 101J-T-A	
C42		S.CERAMIC	C1608 CH 1H 470J-T-A	
C48			C1608 JB 1H 102K-T-A	
C49	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A	
C50		S.CERAMIC	C1608 JB 1H 102K-T-A	
C51		S.CERAMIC	C1608 JB 1H 102K-T-A	
C52		S.CERAMIC	C1608 JB 1E 103K-T-A	
C53	4030006900	S.CERAMIC S.CERAMIC	C1608 JB 1E 103K-T-A C1608 JB 1H 102K-T-A	
C54 C55	4030000000	S.CERAMIC	C1608 CH 1H 040C-T-A	
C56	4030007050	S.CERAMIC	C1608 CH 1H 220J-T-A	
C57		S.CERAMIC	C1608 JB 1H 102K-T-A	
C59		S.CERAMIC	C1608 JB 1 E 103K-T-A	
C60		S.ELECTROLYTIC		
C63		A CANADA PART CANADA	C1608 JB 1E 103K-T-A	
C64	4030006900		C1608 JB 1E 103K-T-A	
C65	4030006900	S,CERAMIC S.CERAMIC	C1608 JB 1E 103K-T-A C1608 JB 1H 102K-T-A	
C66 C67		S.CERAMIC	C1608 CH 1H 470J-T-A	
C68			C1608 CH 1H 470J-T-A	
C69			C1608 JB 1H 102K-T-A	
C70	4030006860	S,CERAMIC	C1608JB 1H 102K-T-A	
C71	and the second second second	S.CERAMIC	C1608 JB 1H 102K-T-A	
C72		S.CERAMIC	C1608 CH 1H 470J-T-A	
C73		S.CERAMIC	C1608 CH 1H 470J-T-A C1608 JB 1H 102K-T-A	
C74 C75		S.CERAMIC S.CERAMIC	C1608 JB 1H 102K-T-A	
C76			C1808 JB 1H 102K-T-A	
C77		S.CERAMIC	C1608 JB 1H 102K-T-A	
C78			C1608 JB 1H 102K-T-A	
079	4030007090	S.CERAMIC	C1608 CH 1H 470J-T-A	
C80		S.CERAMIC	C1608 JF 1C 104Z-T-A	
C81		S.CERAMIC	C1608 JB 1H 102K-T-A	
C82		S.CERAMIC	C1608 JB 1H 102K-T-A	
C83 C84		S.CERAMIC S.CERAMIC	C1608JB 1H 102K-T-A C1608JB 1H 102K-T-A	
C85	4030000000	S.CERAMIC	C1608 CH 1H 470J-T-A	
C86	4030007030	S.CERAMIC	C1808 JB 1H 102K-T-A	
C87		S.CERAMIC	C1608 JB 1H 102K-T-A	
C88		S.CERAMIC	C1608JB 1E 103K-T-A	
C89		S.ELECTROLYTIC		
C90		S.CERAMIC	C1808 JF 1 C 104Z-T-A	
C91		S.CERAMIC S.CERAMIC	C1608 JF 1C 104Z-T-A C1608 JF 1C 104Z-T-A	
C92 C93	10.00	S.CERAMIC	C1608 JB 1C 223K-T-A	
C94		S.CERAMIC	C1608 CH 1H 470J-T-A	
C95	4030007110	S.CERAMIC	C1608 CH 1H 680J-T-A	
DS1	5030001570	LCD	LD-HU10238E	
DS2	5040002060		SML-020MLT T86	
DS3	5040002060	S.LED	SML-020MLT T86	
DS4	5040002060		SML-020MLT T86	
DS5	5040002060		SML-020MLT 186	
D56	5040002060		SML-020MLT T86	
OS7	5040002060		SML-020MLT T86	
DS8	5040002370		SML-010MT T86 SML-010MTT86	
DS9 DS10	5040002370 5040002370		SML-010MT T86 SML-010MT T86	
DS10	5040002370		SML-010MTT86	
DS12	5040002370	The state of the s	SML-010MTT86	
DS13	5040002370	S.LED	SML-010MTT86	
St	2260002440	SSWITCH	EVQ-PPPA25	
S2	2260002440		EVQ-PPPA25	
53	2260002440	AND AND DESCRIPTION OF THE PROPERTY OF THE PRO	EVQ-PPPA25	
S4	2260002440		EVO-PPPA25	
S5	2260002440	S.SWITCH	EVQ-PPPA25	
S6	2260002440		EVQ-PPPA25	
S7	2260002440		EVQ-PPPA25	
S8 S9	2260002 <b>44</b> 0 2250000370	S.SWITCH ENCODER	EVQ-PPPA25 EVQ-VENF0124B	
14	0450004472	COMMECTOS	05000 0884	
J1 J2	6450001470	CONNECTOR CONNECTOR	95003-2881 53244-1217	
J2 J3	6510020880	CONNECTOR	53244-1217	

## [LOGIC UNIT]

REF NO.	ORDER NO.	DESCRIPTION			
W1	7120000470	JUMPER	ERDS2T0	[TIHA] only	
EP1 EP2	0910049542 8930045730	PCB LCD CONTACT	B 5097B SRCN-2088-SP	-N-W	

## [MAIN UNIT]

REF NO.	ORDER NO.		DESCRIPTION
IC1	1130007610	S.IC	μPD3140GS-E1 (DS6)
IC2	1130008560	S.IC	TC75S51F (TE85L)
IC3	1110002750	S.IC	TA75S01F (TE85R)
IC4	1150000130	IC	SC-1005 [THA]only
	1150001950		SC-1091 other
IC5	1180001250		TA7808F(TE1.6L)
106	1110003490	S.IC	TA31136FN (D.EL.)
		10.100	TA75S01F (TE85R)
IC7	1110002750		
IC6	1110002550	A CONTRACTOR OF THE PARTY OF TH	TA7252AP
IC9	1180000420	A Common	TA78L05F (TE12R)
IC10	1130007700		BU4094BCF-T1
IC11	1140003830	S.IC	TC4W66F(TE12L)
	The same of		[EUR], [ITA] only
IC12	1140003830	S.IC	TC4W66F(TE12L)
			(EUR), (ITA) only
Q1	1530002320	S.TRANSISTOR	2SC4226-T2 R25
Q2		S.TRANSISTOR	2SC4226-T2 R25
4.0		STRANSISTOR	DTA113ZU T107
Q3		Control of the Contro	
Q4		S.TRANSISTOR	2SC4226-T2 R25
Q5		S.TRANSISTOR	2SC4226-T2 R25
QB	1530002920	S.TRANSISTOR	2SC4226-T2 R25
Q7	1530002060	S.TRANSISTOR	2SC4081 T107 R
Q11	1530002850	S.TRANSISTOR	2SC4116-BL (TE85R)
Q12	The second secon	S.TRANSISTOR	2SA1734 (TE12R)
		S.TRANSISTOR	2SC3357-T2
Q13			
Q14		S.TRANSISTOR	2SC2954-T2B
Q15		S.TRANSISTOR	DTC144EUA T106
Q16		S.TRANSISTOR	DTC144EUA T106
Q17	1530002850	S.TRANSISTOR	2SC4116-BL (TE85R)
Q18	1530002280	S.TRANSISTOR	2SC4081 T107 S
Q19	1520000730	S.TRANSISTOR	2SB934P (DS)-(TX)
Q20	1580000490		3SK166-2-T7
Q21	1580000490		3SK166-2-T7
Q22		S.TRANSISTOR	2SC4215-Q (TEB5R)
Q23		S.TRANSISTOR	2SC4081 T107 R
Q24		S.TRANSISTOR	2SC4081 T107 R
Q25	1590001390		2SJ144-Y (TE85R)
Q26	1530002970	S.TRANSISTOR	2SC46B4 (TE16R)
Q27	1510000890	S.TRANSISTOR	DTA143TU T107
Q28	1530003090	S.TRANSISTOR	2SC4213-B (TE85R)
Q29		S.TRANSISTOR	DTB123EK T147
Q30		S.TRANSISTOR	DTC144EUAT105
Q31		S.TRANSISTOR	DTB123EKT147
Q32		S.TRANSISTOR	DTC144EUAT106
Q33		S.THANSISTOR	2SC4226-T2 R25
Q35	1590001320	S.TRANSISTOR	DTC143ZUA T106
Q36	1530002850	S.TRANSISTOR	2SC4116-BL (TE85R)
Q37	1530002850	S.TRANSISTOR	2SC4116 BL (TE85R)
Q38		S.TRANSISTOR	2SC4116-BL (TE85R)
400	1000000	0.11	[EUR], [ITA] only
Q40	1590000720	S.TRANSISTOR	DTA144EUA T106 [EUR], [ITA] only
040	45.00000000	CEET	
Q42	1560000840	S.FET	2SK1829 (TEB5R) [EUR], [ITA] only
		- North	All the second
D1	1720000370		HVU350'FAF
D3	1750000550	S.DIODE	1SS355 TE-17
D4	1790000980	S.DIODE	MA742 (TX)
D5	1790000450	C 17 200 40 40 C	MA862 (TX)
D6	1750000370		DA221 TL
		Control of the Contro	The state of the s
D7	1710000310		MI407
D8	1790000980		MA742 (TX)
D9	1790000980	A STATE OF THE PARTY OF THE PAR	MA742 (TX)
D10	1710000230		Mi308
	1710000290	SIONE	Mi308

### [MAIN UNIT]

MAIN UNIT]				
REF NO.	ORDER NO.		DESCRIPTION	
D12	1750000550	S.DIODE	1SS355 TE-17	
D13	1720000370	S.VARICAP	HVU350TAF	
D14	1720000370	S.VARICAP	HVU350TAF	
D15	1720000370	S.VARICAP	HVU350TRF	
D16	1720000370	S.VARICAP	HVU350TAF	
D17	1790000980	S.DIODE	MA742 (TX)	
D18	1730002340	S.ZENER	MA8047-M (TX)	
D19	1750000550		1 SS355 TE-17	
D20	1790000700	CALL AND COMMENT	DSA3A1	
D21	1750000550		1SS355TE-17	
D23	1720000370	A TOTAL OF THE PARTY OF THE PAR	HVU350TRF	
D24	1730000520		RD20E 82	
D25	1750000550		1SS355 TE-17	
FI:	2010002240	MONOLITHIC	FL-288 (15.650 MHz)	
FI2	2020001520		CFWS450F	
FI3	2020001320		CFWS450HT [EUR], [iTA] only	
V4	005000000	NTAI.	CD 540 (45 0 MH)	
X1 X2	6050009820 6070000200	DISCRIMINATOR	CR-549 (15.2 MHz) CDB450C24	
L1	6200004480	S.COIL	MLF1608D R82K-T	
12	6130002480		LB-277	
L3	6200003300	Control for the Control of the Contr	ELJNC R22K-F	
L4	8200003300		ELJNC R22K-F	
L5	6200001620		ELIFC 1ROK-F	
L6	6200007380	C1 2 (10 (2.14 (2.	EWFC 8F12K-F	
	6200007360		ELJRE47NG-F	
L10	THE RESERVE THE PARTY OF THE PA	Committee of the commit	ELIRE 18NG-F	
L11	6200005690	The state of the s		
L12	6200006670	Control of the Contro	ELJRE68NG-F	
L13	6200005710		ELJAE 27NG-F	
L14	6200006570	[21,7] [2] [2]	ELJRE 68NG-F	
L15	6200005740	Control of the Contro	ELJRE 47NG-F	
L16	8170000160	1972-19	LW-19	
L17	6110001550	COIL	LA-235	
L18	6110001560	COIL	LA-236	
L19	6110001610	COIL	LA-244	
L20	6110001550	COIL	LA-235	
1.21	6200004480	Committee of the Commit	MLF1608D R82K-T	
122	6110001550		LA-235	
L23	6110001550		LA-235	
L24	6200004860		MC152-E558CNA-100036	
	6200002180	The second secon	NL252018T-R12J	
1.25				
126	6200004860	COVER TO SERVICE STATE OF THE PARTY OF THE P	MC152-E558CNA-100036	
127	6200004230		ELJNC R56K-F	
1.28	6200004860		MC152-E558CNA-100036	
153	6200004860	Control of the Contro	MC152-E558CNA-100036	
L30	6200001920		ELJNC R15K-F	
L31	6200003300	S.COIL	ELJNC R22K-F	
L32	6200007850	S.COtL	ELJNC R82K-F	
L33	6200002940	S.COIL	ELJFC 1R2K-F	
L34	6200004480	S.COIL	MLF1608D R82K-T	
L35	6200004850	S.COIL	MC152-E558CN-100024	
136	6200004450		ELJFC 6R8M-F	
L37	6200004880	Control of the Contro	ELJFC 3R3K-F	
L38	6200004920		MLF1608A 2R2K-T	
L39	6200004920		MLF1608A 2R2K-T	
R1	7/13/00/2800	S.RESISTOR	ERJ3GEYJ 124 V (120 kΩ)	
		S.RESISTOR	ERJ3GEYJ 101 V (100 Ω)	
R2		the state of the s		
R6	COLD SEE STATE OF SE	S.RESISTOR	ERJ3GEYJ 471 V (470 Ω)	
R7	THE RESERVE OF THE PARTY OF THE	S.RESISTOR	ERJ3GEYJ 333 V (33 kQ)	
R8		S.RESISTOR	ERJ3GEYJ 471 V (470 Ω)	
R9		S.RESISTOR	ERJ3GEYJ 333 V (33 kΩ)	
R10		S.RESISTOR	ERJ3GEYJ 101 V (100Ω)	
R11	A CONTRACTOR OF THE PARTY OF TH	S.RESISTOR	ERJ3GEYJ 101 V (100Ω)	
R12		S.RESISTOR	ERJ3GEYJ 124 V (120 kΩ)	
R13		S.RESISTOR	ERJ3GEYJ 272 V (2.7 kΩ)	
R14	7030003320	S.RESISTOR	ERJ3GEYJ 101 V (100 Ω)	
R15	7030003280	S.RESISTOR	ERJ3GEYJ 470 V (47 Ω)	
R16	7030003320	S.RESISTOR	ERJ3GEYJ 101 V (100Ω)	
R17		S.RESISTOR	ERJ3GEYJ 470 V (47 Ω)	
R18		S.RESISTOR	ERJ3GEYJ 473 V (47 kΩ)	
R19		S.RESISTOR	ERJ3GEYJ 331 V (330 Ω)	
R20		S.RESISTOR	ERJ3GEYJ 383 V (33 kΩ)	
R21		S.RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)	
		S.RESISTOR	ERJ3GEYJ 225 V (2.2 MΩ)	
F122				

## [MAIN UNIT]

REF NO.	ORDER NO.	UIA	DESCRIPTION
R24	A COUNTY OF THE PARTY OF THE PA	S.RESISTOR	ERJ3GEYJ 474 V (470 kΩ)
R25		S.RESISTOR	ERJ3GEYJ 681 V (680 Ω)
R26		S.THERMISTOR	TN20-3W472LT
R27		S.RESISTOR	ERJ3GEYJ 222 V (2.2 kΩ)
R28	7030003480	S.RESISTOR S.RESISTOR	ERJ3GEYJ 222 V (2.2 kΩ) ERJ3GEYJ 472 V (4.7 kΩ)
A30	7030003520		ERJ3GEYJ 472 V (4.7 kΩ)
R31	The second second second second	S.RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)
R32		S.RESISTOR	ERJ3GEYJ 101 V (100 Ω)
R33	7030003300		ERJ3GEYJ 680 V (68 Ω)
R34		S.RESISTOR	ERJ3GEYJ 101 V (100 Ω)
R35	7030000180	S.RESISTOR	MCR10EZHJ 22 Ω (220)
R36	7030003520	S.RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)
R37		S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R38	7030003440	The second secon	ERJ3GEYJ 102 V (1 kΩ)
R39	A CONTRACTOR OF THE PARTY OF TH	S.RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)
R40	7030003430		ERJ3GEYJ 821 V (820 Ω)
R41	7030001130		MCR50JZHJ 100 $\Omega$ (101) MCR10EZHJ 22 $\Omega$ (220)
R42	7030000180	S.RESISTOR S.RESISTOR	ERJ3GEYJ 101 V (100 Ω)
R44	7030003600		ERJ3GEYJ 223 V (22 kΩ)
R45	7030003540		ERJ3GEYJ 682 V (6.8 kΩ)
R46	7030003460	Carlotte and the second	ERJ3GEYJ 152 V (1.5 kΩ)
R47	And the Real Property and the Control of the Contro	S.RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)
			[TPE] only
Die of	7030003490		ERJ3GEYJ 272 V (2.7 kΩ) other
R48	7030003520	S.RESISTOR	ERJ3GEYJ 472 V (4.7 kΩ)
R49	7310002740		RV-150 (RH03A3A14X0FC)103
R50	7030003800	and the same of th	ERJ3GEYJ 105 V (1 MΩ)
R51	7520000120		PTH9M04 BC 22275-2F333
R52	Control of the Contro	S.RESISTOR	ERJ3GEYJ 824 V (820 kΩ)
R53	7030003560		ERJ3GEYJ 103 V (10 kΩ)
R54	7030003640		ERJ3GEYJ 473 V (47 kΩ)
R55	7030003620	Annual State of the Control of the C	ERJ3GEYJ 333 V (33 kΩ) MCR50JZHJ 330 Ω (331)
R57	7030001190		ERJ3GEYJ 103 V (10 kΩ)
R58	7030003300	S.RESISTOR	MCR5QJZHJ 68Ω (680)
1150	7000001110	0.11201011011	(AHT)
	7030001050	S.RESISTOR	MCR50JZHJ 22 Ω (220) other
R59	7030003320	S.RESISTOR	ERJ3GEYJ 101 V (100 Q)
R60	7030003540	S.RESISTOR	ERJ3GEYJ 682 V (6.8 kΩ)
R61	7030003550	S.RESISTOR	ERJ3GEYJ 822 V (8.2 kΩ)
R62	7030003550	S.RESISTOR	ERJ3GEYJ 822 V (8.2 kΩ)
R63	7030003540	S.RESISTOR	ERJ3GEYJ 682 V (6.8 kΩ)
R64	7030003720	70	ERJ3GEYJ 224 V (220 kΩ)
R66 R67	7030003640 7030003680		ERJ3GEYJ 473 V (47 kΩ) ERJ3GEYJ 104 V (100 kΩ)
R68	70300033340		ERJ3GEYJ 151 V (150 Ω)
R69	7030003340		ERJ3GEYJ 102 V (1 kΩ)
R70	7030003720	S.RESISTOR	ERJ3GEYJ 224 V (220 kΩ)
R71	The second secon	S.RESISTOR	ERJ3GEYJ 224 V (220 kΩ)
R72		S.AESISTOR	ERJ3GEYJ 224 V (220 kΩ)
R73	7030003680	S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)
R74		S.RESISTOR	ERJ3GEYJ 271 V (270 Ω)
R75		S.RESISTOR	ERJ3GEYJ 180 V (18 Ω)
A76		S.RESISTOR	ERJ3GEYJ 271 V (270 Ω)
A77	Charles and the second of	S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)
R78	7030003300	S.RESISTOR S.RESISTOR	ERJ3GEYJ 680 V (68 Ω) ERJ3GEYJ 101 V (100 Ω)
R81		S.RESISTOR	ERJ3GEYJ 821 V (820 Ω)
R82	Charles Sanction 1 (1971)	S.RESISTOR	ERJ3GEYJ 182 V (1.8 kΩ)
R83	THE RESERVE TO STREET	S.RESISTOR	ERJ3GEYJ 823 V (82 kΩ)
R85	7030003320		ERJ3GEYJ 101 V (100 Ω)
R86	7310002580		RV-108 (RH03A3A15X05A) 104
R89	7030003530	S.RESISTOR	ERJ3GEYJ 502 V (5.6 kΩ)
R90	7030003440		ERJ3GEYJ 102 V (1 kΩ)
R91	THE RESERVE OF THE PARTY OF THE	S.RESISTOR	ERJ3GEYJ 272 V (2.7 kΩ)
R92	7030003380		ERJ3GEYJ 331 V (330 Ω)
R93		S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)
R98 R100		S.RESISTOR S.RESISTOR	ERJ3GEYJ 223 V (22 kΩ) ERJ3GEYJ 821 V (820 Ω)
R100		S.RESISTOR	ERJ3GEYJ 271 V (270 Ω)
A102		S.RESISTOR	ERJ3GEYJ 561 V (560 Ω)
R103	The second section of the sect	S.RESISTOR	MCR10EZHJ 100 Ω (101)
R104		S.RESISTOR	ERJ3GEYJ 222 V (2.2 kΩ)
215	Name and Advanced	TA THE PARTY OF	[EUR], [ITA] only
- V		S.RESISTOR	ERJ3GEYJ 681 V (680 Ω) other
R105		S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R106	A CONTRACTOR OF THE PARTY OF TH	S.RESISTOR	ERJ3GEYJ 471 V (470 Ω)
R107		S.RESISTOR S.RESISTOR	ERJ3GEYJ 473 V (47 kΩ) ERJ3GEYJ 154 V (150 kΩ)
R108 R109		S.RESISTOR	ERJ3GEYJ 332 V (3.3 kΩ)
11103	, 0000000000	J.I ILUIO I UN	LI 1000L 1 0 00E ¥ (0.0 MZ)

## [MAIN UNIT]

REF NO.	ORDER NO.	DESCRIPTION	
R110		S.RESISTOR	ERJ3GEYJ 333 V (33 kΩ)
R111	7510000830	S.THERMISTOR	NTCCF2012 3EH 471KC-T
	and the state of		(EUR), (ITA) only
0440		S.RESISTOR	MCR10EZHJ 10 Ω (100) othe
R113	the state of the s	S.RESISTOR	ERJ3GEYJ 622 V (8.2 kΩ)
R114 R115		S.RESISTOR S.RESISTOR	ERJ3GEYJ 123 V (12 kΩ) ERJ3GEYJ 223 V (22 kΩ)
R116		S.RESISTOR	ERJ3GEYJ 393 V (39 kΩ)
A117		SAESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R118		S.RESISTOR	ERJ3GEYJ 225 V (2.2 MΩ)
R119	7030003380	S.RESISTOR	ERJ3GEYJ 331 V (330 Ω)
R120	7030003600	S.RESISTOR	ERJ3GEYJ 223 V (22 kΩ)
R121		S.RESISTOR	ERJ3GEYJ 473 V (47 kΩ)
R122		S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R123		S.RESISTOR	ERJ3GEYJ 474 V (470 kΩ)
R124	All the County of the State County	S.RESISTOR	ERJ3GEYJ 152 V (1.5 kΩ)
R125	1 1 1 1 1 1 1 1 1 1 1 1	S.RESISTOR S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)
R127	The second second second second	S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ) ERJ3GEYJ 333 V (33 kΩ)
R128		S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)
R129		S.RESISTOR	ERJ3GEYJ 273 V (27 kΩ)
R130		SRESISTOR	ERJ3GEYJ 104 V (100 kΩ)
R131		SAESISTOR	ERJ3GEYJ 104 V (100 kΩ)
R132	A Committee of the Comm	S.RESISTOR	ERJ3GEYJ 124 V (120 kΩ)
R133	7030001010	S.RESISTOR	MCR50JZHJ 10 Ω (100)
R134	7030003440	S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R136	7030003620		ERJ3GEYJ 333 V (33 kΩ)
R137	The second secon	S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R138	COLUMN TO SERVICE AND ADDRESS OF THE RESERVE	S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
A139	THE CONTRACT OF THE PARTY OF TH	S.RESISTOR	ERJ3GEYJ 220 V (22 Ω)
R140		S.RESISTOR	ERJ3GEYJ 823 V (82 kΩ)
R141		S.RESISTOR	ERJ3GEYJ 4R7 V (4.7 Ω)
R142		S.RESISTOR S.RESISTOR	ERJ3GEYJ 272 V (2.7 kΩ) ERJ3GEYJ 103 V (10 kΩ)
R146		S.RESISTOR	ERJ3GEYJ 100 V (10 Ω)
R148	THE R. P. LEWIS CO., LANSING, MICH. 49, 120, 121, 121, 121, 121, 121, 121, 121	S.RESISTOR	ERJ3GEYJ 562 V (5.6 kΩ)
R149	The second secon	S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R150		S.RESISTOR	ERJ3GEYJ 102 V (1 kΩ)
R151		S.RESISTOR	ERJ3GEYJ 104 V (100 kΩ)
R152	The second secon	S.RESISTOR	ERJ3GEYJ 123 V (12 kΩ)
R154	7030003560	S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
R155	7030003450	S.RESISTOR	ERJ3GEYJ 122 V (1.2 kΩ)
			[EUR], [ITA] only
R156	7030003640	S.RESISTOR	ERJ3GEYJ 473 V (47 kΩ) [EUR], [ITA] only
R157	7030003640	S.RESISTOR	ERJ3GEYJ 473 V (47 kΩ)
Towns.	- Lorentz desk	Committee &	[EUR], [ITA] only
A159		S.RESISTOR	ER./3GEYJ 223 V (22 kΩ)
R160	7030003550	S.RESISTOR	ERJ3GEYJ 822 V (8.2 kΩ)
A161	7030003680	S.RESISTOR	[EUR], [ITA] only ERJ3GEYJ 104 V (100 kΩ)
		S. 125.6 / G. 1	[EUA], [ITA] only
<b>R163</b>	7310002740	S.TRIMMER	RV-150 (RH03A3A14X0FC) 103
R164		S.THERMISTOR	NTCCM1608 4LH 104KC
R165	10.00	S.RESISTOR	ERJ3GEYJ 683 V (68 kΩ)
R166		S.RESISTOR	ERJ3GEYJ 331 V (330 Ω)
R167	1 2 2 2 2 2 2 2 2	SAESISTOR	ERJ3GEYJ 103 V (10 kΩ)
A168	7030003560	S.RESISTOR	ERJ3GEYJ 103 V (10 kΩ)
C1	4030006860	SCERAMO	C1608 JB 1H 102K-T-A
C2	4030007050		C1608 CH 1H 220J-T-A
Ca	4030007030		C1608 JB 1H 102K-T-A
C6	4030006860		C1608 JB 1H 102K-T-A
C7	4030006910		C1608CH 1H 0R5C-T-A
C8	4030006860		C1608 JB 1H 1 02K-T-A
C9		S.CERAMIC	C1608 CH 1H 0R3B-T-A
C10	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C11	4030006B60		C1608 JB 1H 102K-T-A
C13	4030006910		C1608 CH 1H 0R5C-T-A
C14	4030006B60		C1608 JB 1H 102K-T-A
C15	4030006860		C1608 JB 1H 102K-T-A
C16	4030007060		C1608 CH 1H 270J-T-A
C17	4030006970		C1608 CH 1H 060D-T-A
C18	4030007060		C1608 CH 1H 270J-T-A
C19	4030006860		C1608JB 1H 102K-T-A
C20	4030010780		C1608 CH 1H 1R5C-T-A
C21 C22	4030006860		C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
C23	4030006860		C1608 JB 1H 102K-T-A
JEU		S.ELECTROLYTIC	ECEVICA100SR
C24	45100046301	SELECTED ATM.	

## [MAIN UNIT]

REF NO.	ORDER NO.		DESCRIPTION
C26	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C27	4030006860		C1608JB 1H 102K-T-A
C28	4030006860		C1608 JB 1H 102K-T-A
C29	4030006860		C1608 JB 1 H 102K-T-A
C30	4030006860 4550006470	A R. A. Lander, Tolland St. Landson, Co.	C1608 JB 1H 102K-T-A TEMSVB2 1D 106M-8L
C32	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C33	4030007050	S.CERAMIC	C1608CH 1H 220J-T-A
C34		S.CERAMIC	C1608CH 1H 220J-T-A
C35	4030006860		C1608 J B 1 H 102 K-T-A
C36	4030006860	S.CERAMIC	C1608 JB 1 H 102K-T-A
C37	4030006860		C1608 JB 1 H 102K-T-A
C39	4030006860		C1608 JB 1H 102K-T-A
C40 C41	4030006860 4030006930	S.CERAMIC S.CERAMIC	C1608 J B 1 H 102K-T-A C1608 CH 1H 020C-T-A
C42		S,CERAMIC	C1608 JB 1H 102K-T-A
C43	4030007010	Carl Latin Adia 1	C1608 CH 1H 100D-T-A
C44	4030007020	S.CERAMIC	C1608 CH 1H 120J-T-A
C45	4030006880	S.CERAMIC	C1608 JB 1 H 102K-T-A
C46	4030006860	S.CERAMIC	C1608JB 1H 102K-T-A
C47	4030007050	S.CERAMIC	C1608 CH 1H 220,1-T-A
C48 C49	4030007040	S.CERAMIC S.CERAMIC	C1608 CH 1H 180J-T-A C1608 CH 1H 180J-T-A
C50		S.CERAMIC	C1608 JB 1H 102K-T-A
C51		S.CERAMIC	C1608 J B 1H 102K-T-A
C52	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C53	4030011120	S.CERAMIC	GRM42-6 CH 100D 500PT
C55	4010005790		HM60SJ YB 102K 500V
C56	4030011170	S.CERAMIC	GRM42-6 CH 180J 500PT
C57 C58	4010007630		HM60SJ CH 270J 500V GRM42-6 CK 010C 500PT
C59	4030011020	S.CERAMIC	C1608 CH 1H 120.J-T-A
C60	4030011020	The second secon	GRM42-6 CK 010C 500PT
C61	4030007020	S.CERAMIC	C1608 CH 1H 120J-T-A
C62	4030011190	S.CERAMIC	GRM42-6 CH 270J 500PT
C63	4030011190	S.CERAMIC	GRM42-6 CH 270J 500PT
C64	4030011160	S.CERAMIC	GRM42-6 CH 150J 500PT
C65 C66	4030006860 4010005540	S.CERAMIC CERAMIC	C1608 JB 1H 102K-T-A HM60SJ SL 030C 500V
C67	4030007050	The second second second	C1608 CH 1H 220J-T-A
C69	4030006860	7.00	C1608 JB 1H 102K-T-A
C70		S.CERAMIC	C1608 CH 1H 050C-T-A
C72	4030007080	S.CERAMIC	C1608 CH 1H 390,I-T-A
C73	4030006940	S.CERAMIC	C1608 CH 1H 030C-T-A
C74	4030006860 4030006860		C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
C75 C76		S.CERAMIC	C1608 JB 1H 102K-T-A
C77	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C78	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C79	4030006970	S.CERAMIC	C1608 CH 1H 0600-T-A
C80		S.CERAMIC	C1608 CH 1H 300J-T-A
C81 C82		S.CERAMIC S.CERAMIC	C1608 CH 1H 020C-T-A C1608 CH 1H 010C-T-A
C83		S.CERAMIC	C1608 CH 1H 050C-T-A
C84	4030007080		C1608 CH 1H 390J-T-A
C85	4030006920		C1608 CH 1H 010C-T-A
C88		S.CERAMIC	C1608 CH 1H 010C-T-A
C87		S.CERAMIC	C1608 CH 1H 060D-T-A
C88 C89		S.CERAMIC S.CERAMIC	C1608 CH 1H 390,J-T-A C1608 CH 1H 030C-T-A
C90		S.CERAMIC	C1608 CH 1H 070D-T-A
C91		S.CERAMIC	C1608 JB 1H 102K-T-A
C92		S.CERAMIC	C1608 CH 1H 101J-T-A
C93		S.CERAMIC	C1608 JB 1H 102K-T-A
C94	4030006860	A STATE OF THE PARTY OF THE PAR	C1608JB 1H 102K-T-A
C95	4030008960		C1608 CH 1H 050C-T-A
C96 C97		S.CERAMIC S.CERAMIC	C1608JB 1H 102K-T-A C1608JB 1H 102K-T-A
C99	4030007120		C1608 CH 1H 820,J-T-A
C100		S.CERAMIC	C1608 JB 1H 102K-T-A:
C101	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C102		S.CERAMIC	C2012 JF 1C 105Z-T-A
C103	4030006860	The second of the later of the	C1608 JB 1H 102K-T-A
C105	4550000530 4030006860	S.TANTALUM S.CERAMIC	TESVA 1V 104M1-8L C1608 JB 1H 102K-T-A
C107	4550000530	S.TANTALUM	TESVA 1V 104M1-8L
C108		S.TANTALUM	TESVA 1A 225M1-8L
C109	4030006900	S.CERAMIC	C1608 JB 1E 103K-T-A
C111	4030007020		C1608 CH 1H 120J-T-A
C112	4030007020		C1608 CH 1H 120J-T-A
C113	4030006930	S.CERAMIC S.CERAMIC	C1608 CH 1H 020C-T-A C1608 CH 1H 050C-T-A
0114	4030000300	O.OLARIVIIC	01000 011 171 0300-1-A

## [MAIN UNIT]

REF NO.	ORDER NO.	D	ESCRIPTION
C116	4030001830	S.CERAMIC	GRM40 RH 330J 50PT
C117	4030001820	S.CERAMIC S.CERAMIC	GRM40 RH 220J 50PT
C118	4030001610	S.CERAMIC	GRM40 RH 180J 50PT
C119	4030006960	S.TRIMMER S.CERAMIC	C1Z3S-30C-W1-AF C1608 JB 1H 102K-T-A
C128	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C129	4030008630	I S.CERAMIC	C1608 JF 1C 104Z-T-A
C130	4030005110	S.CERAMIC	C2012 JB 1 E 473K-T-A
C131	ANGIOLOGIA	S CERAMIC	C1608 JB 1 C 223K-T-A
C132	4030007130	S.CERAMIC	C1608 CH 1H 101J-T-A
C133	4030006860	S.CERAMIC S.CERAMIC S.CERAMIC	C1608 JB 1H 102K-T-A
C134	4030008680	S.CERAMIC	C2012 JF 1C 1 05Z-T-A C1608 JB 1H 102K-T-A
C136	4030000000	3.ULINIVIIU	C2012 JF 1C 105Z-T-A
C137	4030008560	S CERAMIC	C1608 CH 1H 300J-T-A
C139	4030007170	S.CERAMIC S.CERAMIC S.CERAMIC	C1608 CH 1H 221J-T-A
C140	4030007170	S.CERAMIC	C1608 CH 1H 221J-T-A
C141	4030006850	S.CERAMIC	C1608 JB 1H 471K-T-A
C142	4030008630	S.CERAMIC S.CERAMIC	C1608 JF 1C 104Z-T-A
C143	4030006900	S.CERAMIC	C1608 JB 1E 103K-T-A
C144	4030006860	S.CERAMIC S.CERAMIC	C1608 JB 1C 153K-T-A C1608 JB 1H 102K-T-A
C145	4030008900	S.CERAMIC	C1608 JB 1C 333K-T-A
C147	4030008860		C1608 JB 1C 153K-T-A
C148	4030008770	S.CERAMIC	C1608 JB 1H 562K-T-A
C149	4030008770	S.CERAMIC	C1608 JB 1H 582K-T-A
C150	4030008660	S.CERAMIC	C2012 JF 1C 105Z-T-A
C151	4030008630	S.CERAMIC	C1608 JF 1C 104Z-T-A
C152	4030006860	S.CEHAMIC	C1608 JB 1H 102K-T-A C1608 JB 1E 103K-T-A
C153	4030000900	CCEDAMIC	C1608 IR 1H 102K-T-A
C155	4030006860	S CERAMIC	C1608JB 1H 102K-T-A
C156	4030006860	S.CERAMIC	C1608 JR 1H 102K-T-A
C157	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A 16 MV22 0H 102K T A
C158	4510006020	ELECTROLYTIC	16 MV2200HC
C159	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
C160	4030006860	S.CEHAMIC	C1608 JB 1H 102K-T-A
C161	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
C162		S.ELECTROLYTIC	
C164	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C165	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
C166	4510004640	S.ELECTROLYTIC S.ELECTROLYTIC	ECEV1CA470SP
C167	4510004630	S.ELECTROLYTIC	ECEV1CA100SR
C168	4030006860	S.CERAMIC	C1608JB 1H 102K-T-A
C169		S.ELECTROLYTIC	
C170	4030006860	S.ELECTROLYTIC	C1608 JB 1H 102K-T-A
C172		S.ELECTROLYTIC	
C173		CHARLES TO SECURE A SECURITION OF THE PARTY.	C1608 JB 1H 102K-T-A
C174		S.ELECTROLYTIC	
C175	4510004440	S.ELECTROLYTIC	ECEV1HA010SR
C176		S.TANTALUM	ECST1VY224R
C177		S.ELECTROLYTIC	ECEVICA470SP
C178	4510006260 4030006860	S.ELECTROLYTIC	C1608JB 1H 102K-T-A
C179 C180	4030006860	the contract of the contract o	C1608 JB 1H 102K-T-A
C181		S.ELECTROLYTIC	
C182		S.ELECTROLYFIC	ECEVICA100SR
C183	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C184		S.CERAMIC	C1608 JB 1H 102K-T-A
C185		S.CERAMIC	C1608 JB 1H 102K-T-A
C186		S.CERAMIC	C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
C187	4030006860	S.CERAMIC S.CERAMIC	C1608 JB 1H 102K-T-A
C189		S.CERAMIC	C1608 JB 1H 102K-T-A
C190	4030006860		C1608JB 1H 102K-T-A
C191	4030006860	S.CERAMIC	C1608JB 1H 102K-T-A
C192	4030006860		C1608 JB \$H 102K-T-A
C193		S.CERAMIC	C1608 JB 1H 102K-T-A
C194		S.CERAMIC	C1608JB 1H 102K-T-A
C195	4030006860	S.CERAMIC S.CERAMIC	C1608JB 1H 102K-T-A C1608 JB 1H 102K-T-A
C196	4510005870	S.ELECTROLYTIC	ECEV1HA3R3SR
C198	4030006860		C1608 JB 1H 102K-T-A
C199	4030006860		C1608JB 1H 102K-T-A
C200		S.ELECTROLYTIC	ECEV1CA100SR
C201		S.ELECTROLYTIC	The second secon
C202		S.ELECTROLYTIC	ECEVICA100SR
C203	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C204	4030006660	SCERAMIC	C1608 J B 1 H 102K-T-A

## [MAIN UNIT]

NO.	ORDER NO.	D	ESCRIPTION
C206		S.CERAMIC	C1608 CH 1H 101J-T-A
C207		S.CERAMIC	C1608 CH 1H 360J-T-A
C208			C1608 CH 1H 080D-T-A
		e 11	
C209	4030007000	S.CERAMIC	C1608 CH 1H 090D-T-A
C210	4030006860	P. D. San and A. S. San and A.	C1608JB 1H 102K-T-A
C211	4030009570	S.CERAMIC	C1608 CH 1H 0R3B-T-A
C214	4030006850	S.CERAMIC	C1608 JB 1H 471K-T-A
C215	4030006900		C1608 JB 1 E 103K-T-A
C218			C1608 JB 1H 102K-T-A
C219	4020006860	S.CERAMIC	C1608 JB 1H 102K-T-A
	4030000000	S.CERAMIC	C1608 JF 1C 104Z-T-A
C220		S.CERAMIC	C1000 JF 1C 1042-1-A
C221		S.CERAMIC	C1608 JF 1C 104Z-T-A
C222		And the state of the same	C1608 JB 1 H 102K-T-A [EUR], [1TA] on
C223	100	SELECTROLYTIC	
C224		S.CERAMIC	C1608JB 1H 102K-T-A
C225	4030006860	S.CERAMIC	C1608JB 1H 102K-T-A
C226		S.CERAMIC	C1608 JB 1H 102K-T-A
C227	- 1 / 1/////	S.CERAMIC	no [ATI] (RUE)
			(EUR), [ITA] on
C228		S.ELECTROLYTIC	
C229			C1608 CH 1H 010C-T-A
C230	4510005860	S.ELECTROLYTIC	ECEV1HA2R2SR
C231			C1608 JB 1C 104KT-N
C232			C1608 JB 1H 102K-T-A
	4030000000		
C233	4030006B60	S.CEHAMIC	C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
C234	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C235	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C236	4030006860	S.CERAMIC S.CERAMIC	C1608 JB 1H 102K-T-A
C237	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C238	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A C1608 JB 1H 102K-T-A
C239			C1608 JB 1H 1 02K-T-A
	4030000000	S.CERAMIC	C1609 ID 1H 102K T A
C240	4030006060	S.CERAMIC	C1608 JB 1H 1 02K-T-A C1608 JB 1H 102K-T-A
C241			C1608 JB 1H 102K-1-A
C242			C1608 JB 1H 102K-T-A
C243	4030006860	S.CERAMIC	C1608 JB 1H 102K-T-A
C244	4030008680	S.CERAMIC	C2012 JF 1C 105Z-T-A
J2	6510018040	CONNECTOR	52330-1217
	C510010040	CONNECTOR	52330-1217
13	0510010040	COMMECTOR	
J4 J5		CONNECTOR S.CONNECTOR	HS.10912-01-020 B2B-ZR-SM3-TF
W1	890000488	CABLE	OPC-465
W2		S.JUMPER	ERJ3GE JPW V
W3		JUMPER	ERDS2T0
		S.JUMPER	ERJ3GE JPW V
W5	7030003660	S.JUMPEN	
W6	7030003860	S.JUMPER	except [EUR], [IT/ ERJ3GEJPWV
W7	7030003860	S.JUMPER	except [EUR], [IT/ ERJ3GEJPWV
W8		S.JUMPER	ERJ3GE JPW V
		S.JUMPER	ERJ3GE JPW V
W9 W10	Committee Tolking St.	S.JUMPER	ERJ3GE JPW V
EP1	0910049552	PCB	B 5098B
La F		TUBE	0.7(d) L=14 mm

S.=Surface mount

## SECTION 6 MECHANICAL PARTS AND DISASSEMBLY

## [CHASSIS PARTS]

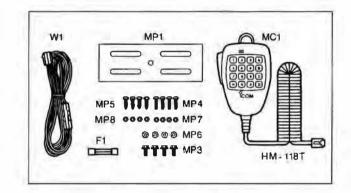
REF. NO. ORDER NO. J1 6510004880		DESCRIPTION	QTV.	
		Antena connector MR-DSE-01	1	
SP1	2510000820	Speaker VS-57-0814	1	
MP1	8010017280	2088 chassis	1	
MP2	8110006430	2088 cover (Include felt, speaker net)	1	
MP4	8930045600	2088 SP rubber	1	
MP5	8810008660	Screw PH BO M3x8 NI-ZU (BT)	2	
MP6	8810008660	Screw PH BO M3x8 NI-ZU (BT)	7	
MP7	8810009610	Screw FH M2.6x6 ZK	4	
MP8	8810005160	Hex socket boit M3x20 ZK	2	
MP9	8810008660	Screw PH BO M3x8 NI-ZU (BT)	2	
MP10	8810008660	Screw PH BO M3x8 Ni-ZU (BT)	1	
MP15	8930039610	Thermally sheet (C)	3	
MP16	8930041160	Themally sheet (G)		

## [ACCESSORIES]

REF. NO.	ORDER NO.	DESCRIPTION	1		
F1	5210000080	Fuse (20A)			
MC1	Optional product	Microphon HM-97 [EUR], [ITA]	1		
	Optional product	Microphon HM-98S [TPE], [USA]	1.1		
	Optional product	Microphon HM-118 [SEA]	1		
	Optional product	Microphon HM-118T [THA], [LA]	1		
W1	8900003760	Cable OPC-346	1		
MP1	8010016380	1542 Mobil bracket (B)	1 4		
MP3	8820000530	Flange bolt M4x8			
MP4	8810000470	Screw PH M5x12 (+/-)			
MP5	8810000950	Screw PH A0 M5x16			
MP7	8850000150	Flat washer M5 Nt BS			
MP8	8830000120	NutM5			

## [LOGIC UNIT]

REF. NO.	EF. NO. ORDER NO. DESCRIPTION			
R61	7210001870	Variable resistor EVU-F2AF20A14 [VOL]	1	
R62	7210001860	Variable resistor EVU-F2AF20B14 [SQL]	1	
DS1	5030001570	LCD £D-HU10238E	1	
S9	2250000370	Encoder EVQ-VENF01 248	1	
EP2	8930045730	LCD contact SRCN-2088-SP-N-W	1	
MP1	8210015290	2088 Reflector	1	
MP2	8930045610	2088 LCD filter	1	
MP3	8210015381	2088 Front panel (A)-1 [THA] only	1	
	8210015281	2088 Front panel-1 other	1	
MP4	8510011580	2088 Front plate	1	
MP5	8930045580	2088 2-button	1	
MP8	8930045590	2088 6-button	1	
MP7	8610010610	Knob N-266	1	
MP8	8610010601	Knob N-267-1	2	
MP10	8810008760	Screw PH BO M2x8 NI-ZU (BT)		
MP11	8930047310	Sponge (FW)	1	



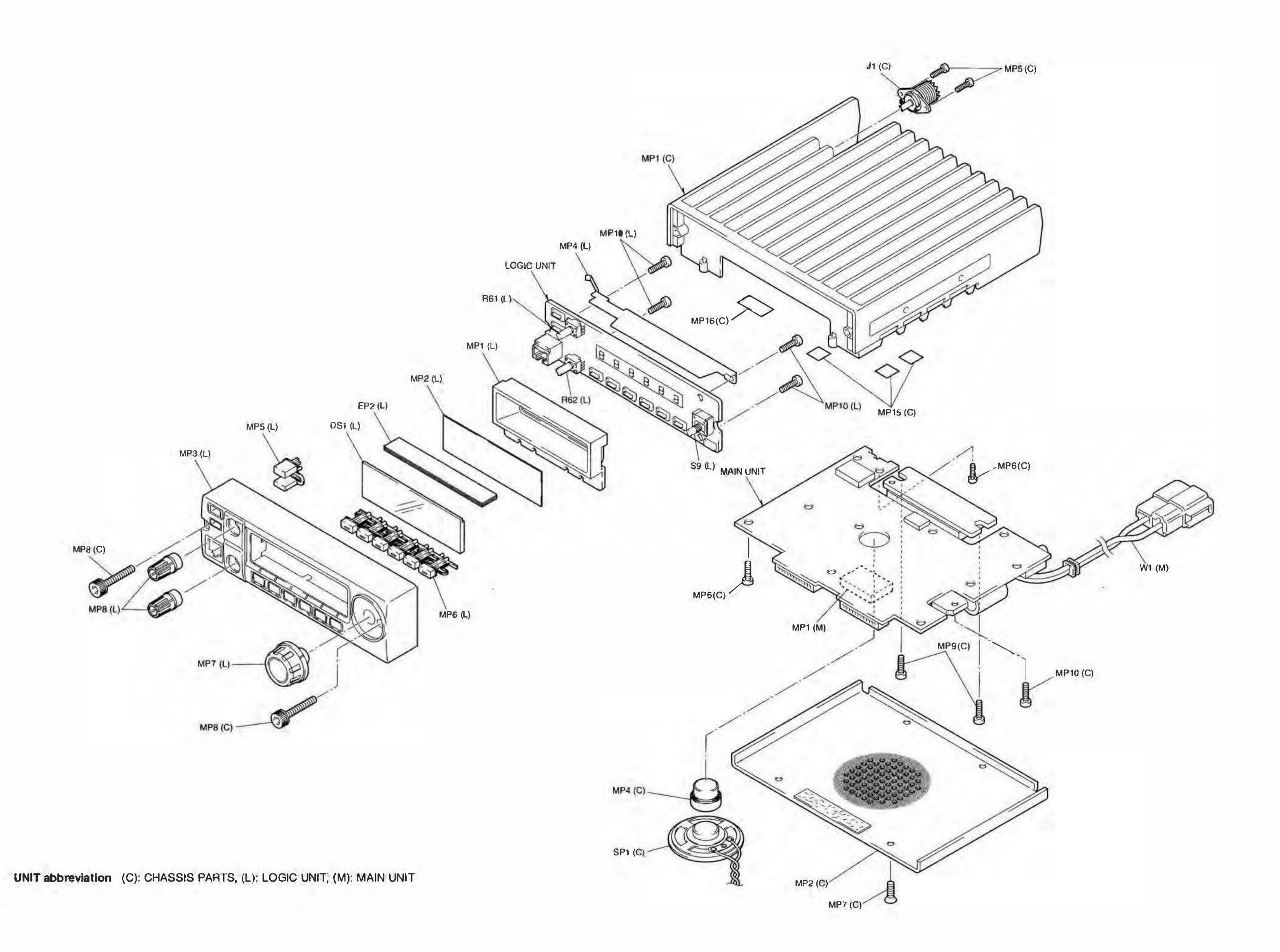
## [MIAN UNIT]

REF. NO. ORDER NO.		DESCRIPTION	QTV.
W1	8900004880	Cable OPC-465	1
MP1	8510011660	2088 VCO case	1

Screw abbreviations

A, 80, BT: Self-tapping

PH: Pan head FH: Flat head BiH: Bind head NI: Nickel SUS: Stainless ZK: Black



## SECTION 7 SEMI-CONDUCTOR INFORMATION

## • TRANSISTOR AND FET'S

2SA1576 R (Symbol: FR)	2SA1734 Q (Symbol: LB)	2SC2954 (Symbol: QK)	2SC3357 (Symbol: RK)	2SC4081 R (Symbol: BR)
B			c c c	B
2SC4081 S (Symbol: BS)	2SC4116 BL (Symbol: LL)	2SC4213 B (Symbol: AB)	2SC4215 Q (Symbol: QO)	2SC4226 R25 (Symbol: R25)
	B C C			B C C
2SD999 CK (Symbol: CK)	2SJ144 Y (Symbol: VY)	2SK1829 (Symbol: KI)	3SK 166 2 (Symbol: K)	DTA113 ZU (Symbol: 111)
c c	\$	s	\$ \$ 61	
DTA114 EU (Symbol: 14)	DTA143 TUA (Symbol: 93)	DTA144 EU (Symbol: 16)	DTB123 EK (Symbol: F12)	DTC143 ZU (Symbol: 123)
B	B	B. C	E C	B □ □ □ □ □ □ □ □ □ □ □ □ □ □ □ □ □ □ □
DTC144 EU (Symbol: 26)	DTC144 TU (Symbol: 06)			
B C	8			
E	€ 🔱			

## • DIODES

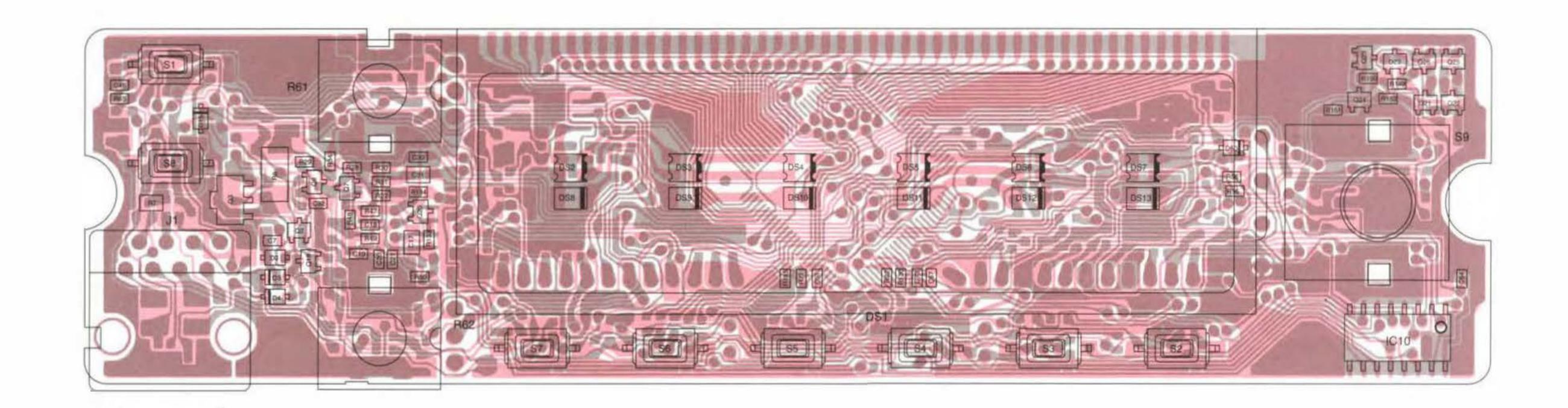
1SS355	DA114	DA115	OA204U	DA221
(Symbol: A)	(Symbol: AV)	(Symbol: AU)	(Symbol: K)	(Symbol: K)
DAN202 U	HVU350	MA742	MA862	MA8047 M
(Symbol: N)	(Symbol: 4)	(Symbol: M1U)	(Symbol: M1I)	(Symbol: 4-7)
MA8091 M (Symbol: 9-1)	- <del>N</del>			<b>1</b>
(Symbol: 9-1)				

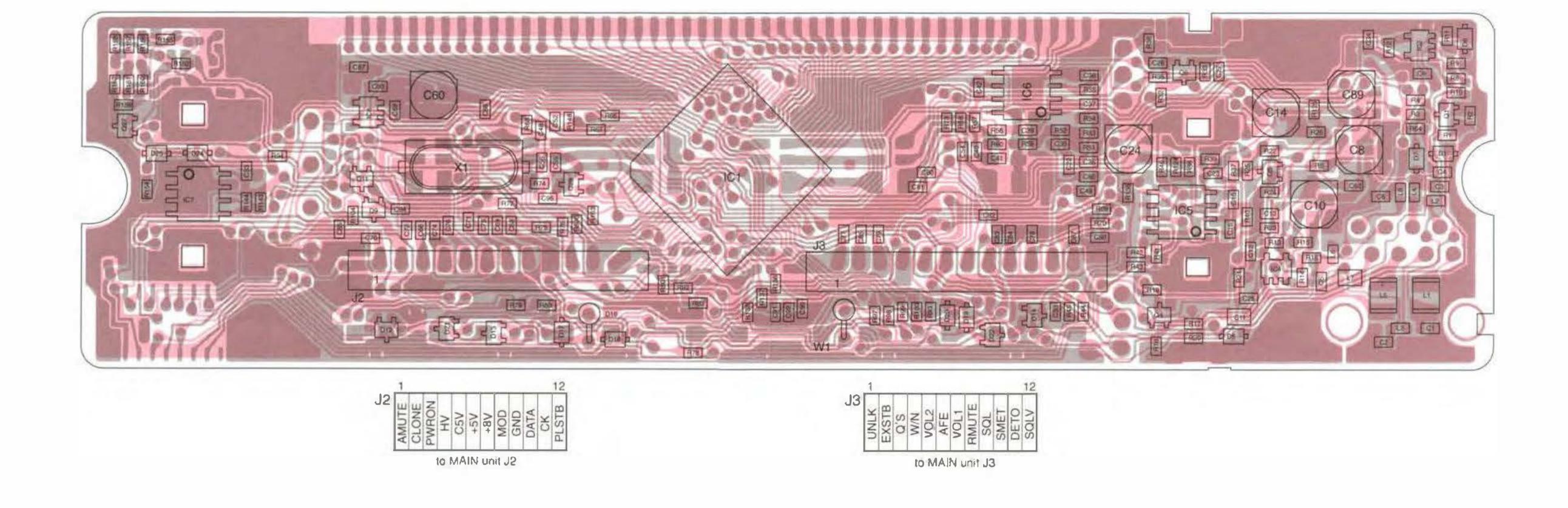
## SECTION 8 BOARD LAYOUTS

to Microphone

8-1 LOGIC UNIT

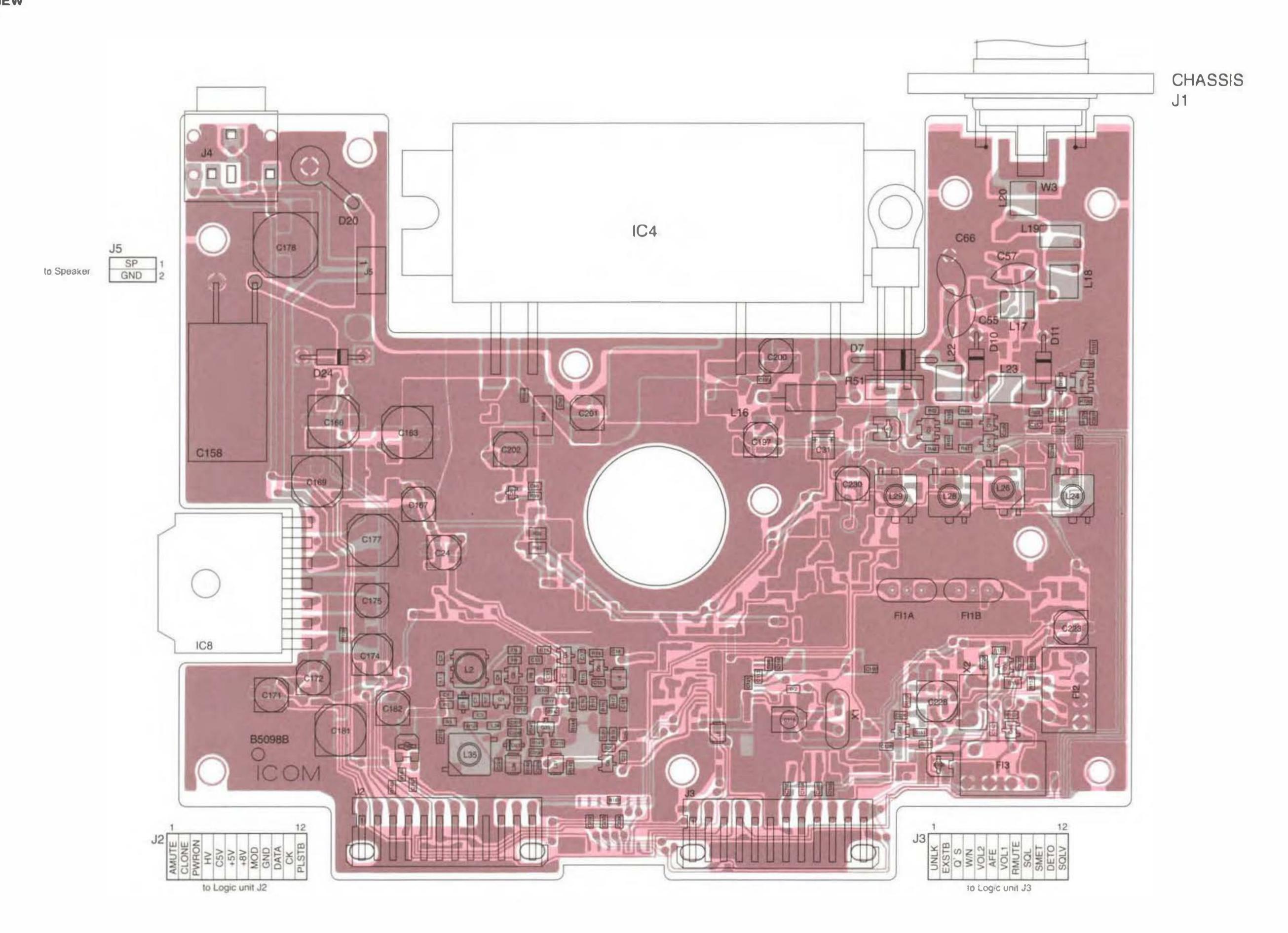
TOP VIEW



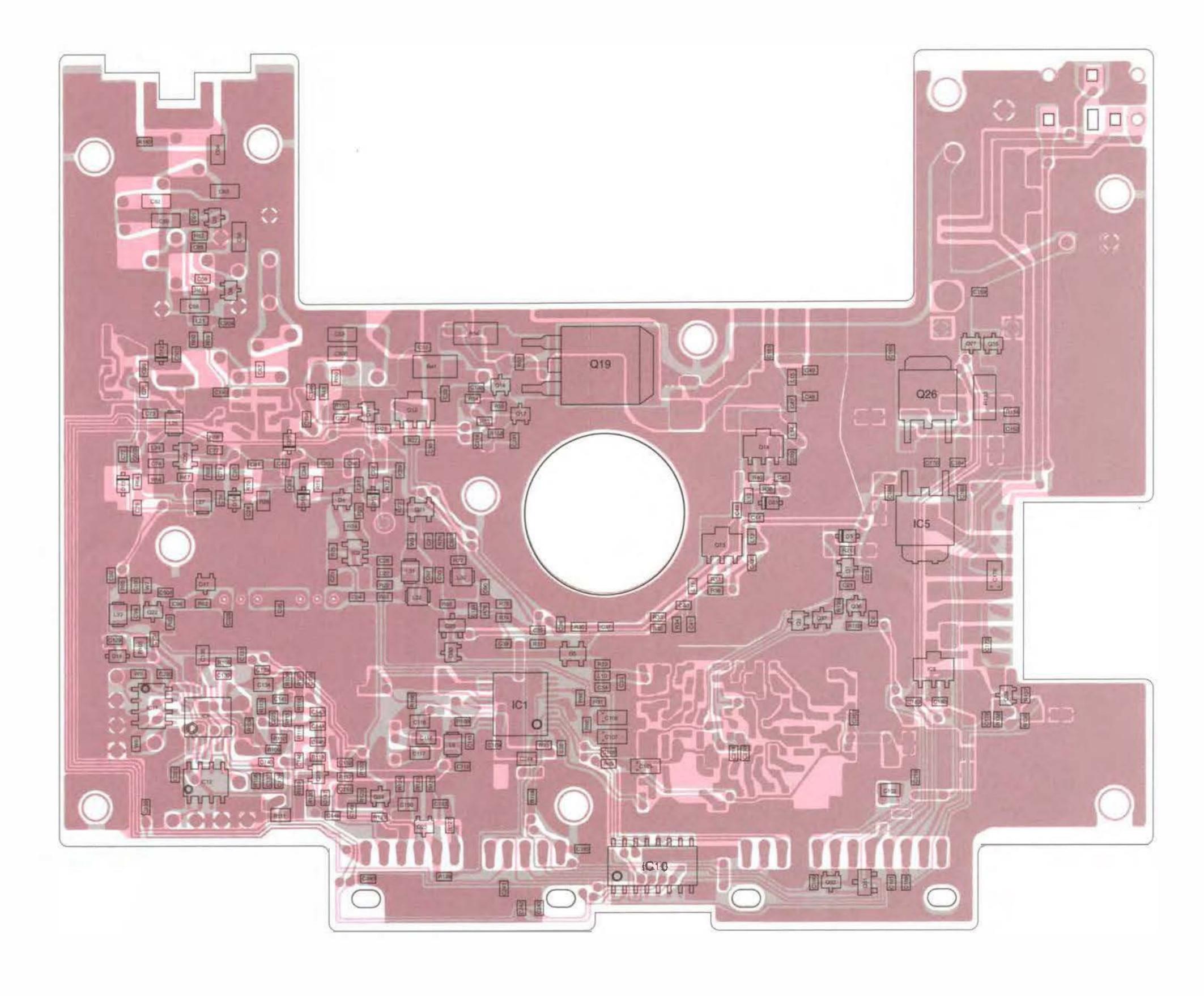


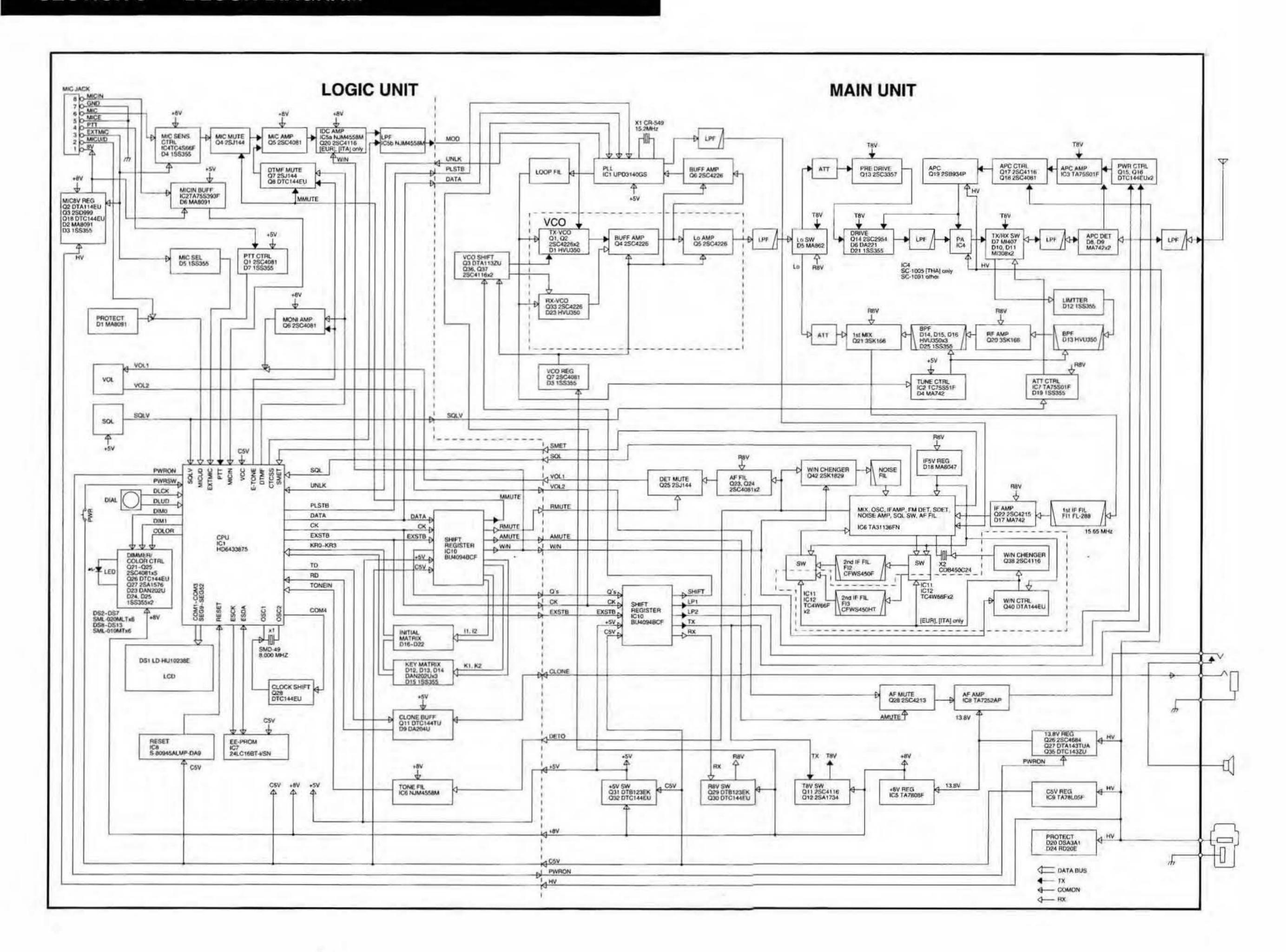
## 8-2 MIAN UNIT

## • TOP VIEW

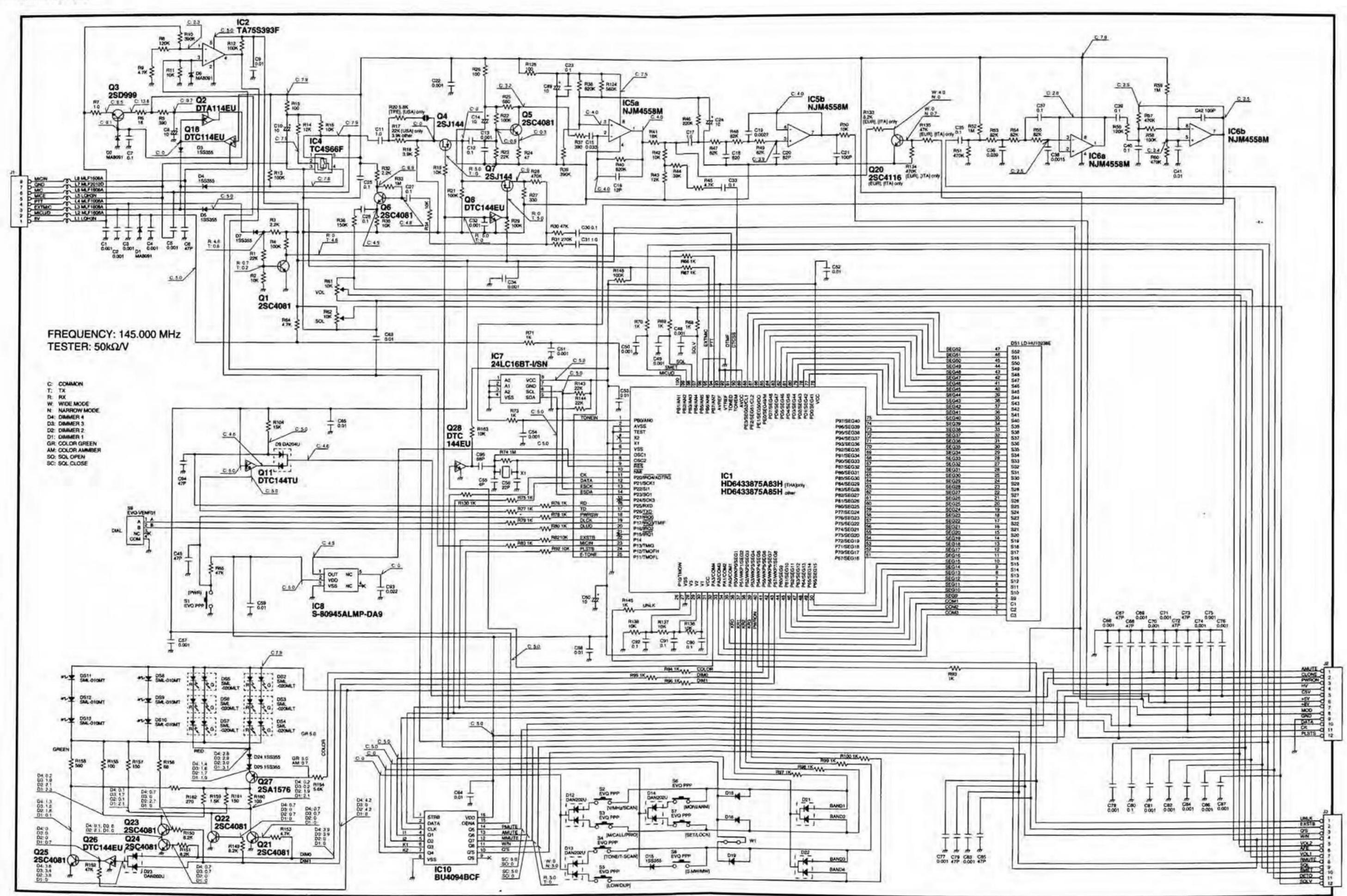


## BOTTOM VIEW

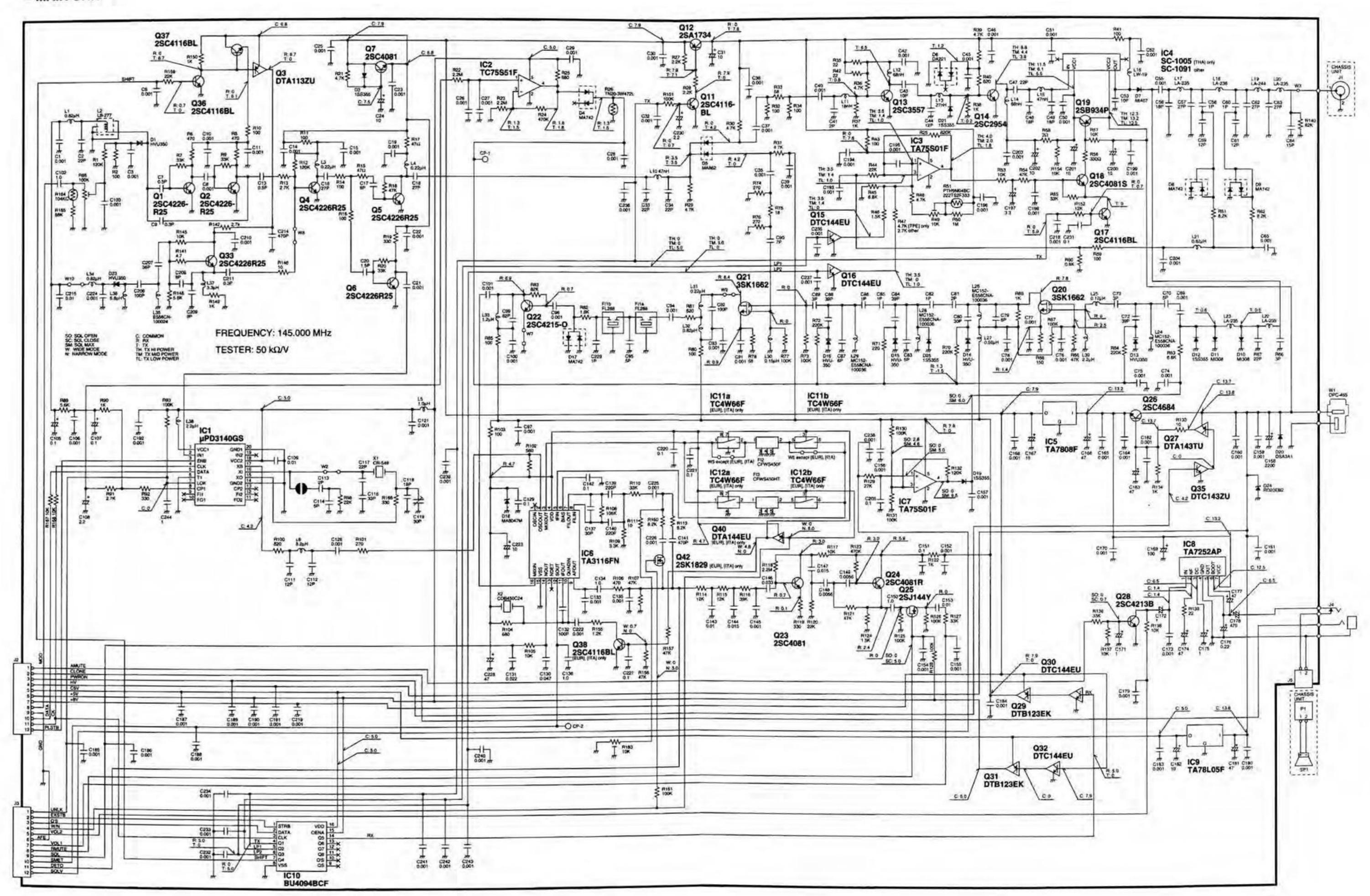




## LOGIC UNIT



## MAIN UNI



## Icom Inc.

6-9-16. Kamihigashi, Hirano-ku, Osaka 547-0002. Japan

Phone: 06 793 5302 Fax : 06 793 0013

#### Icom America Inc.

COrporate Haadquariars>
2880 11 th Ayemus N.E., Selevus, WA 88004, U.S.A.
Phumb (425) 454-8156 Faix. (425) 454-1509
URL : http://www.icom/america.org/

Customer Services Phone: (425) 454-7619

#### Icom Canada

A Division of form America Inc. 3071 #5 Road, Unil 9. Richmond, B.C. V6X 2T4, Canada Phone: (604) 273-7400 Fax: (684) 273-1909

### Icom (Australia) Pty. Ltd.

A.C. N. 008 092 575 290-294 Albert Street, Brunswick, Victoria, 3056, Australia Phone: 03 9387 0866 Fax: 03 9387 0022

#### Asia Icom Inc.

6F No. 68. Sec 1 Chang-Yah Road, Taipei, Taiwan R.O.C.

#### Icom (Europe) GmbH

Communication Equipment Hammelgeister Str. 100. 0-40225 Odesteland, Germany Phone: 0211 348047 Fax: 0211 333639 URL: http://www.icomeurope.com

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Urii. 9, Sea St., Herve Bay, Kent. C16 BLD, U.K. Phone: 01227 741741 Fax: 01227 741742 URL: http://www.tcomuk.co.uk

## Icom France S.a

Zec de la Pláine, Aue Brihdelonc des Motilinais BP 6804, 31505 Toulouse Cedex, France Phone: 561 360303 Fax: 561 3603 80 URL: http://www.icom-france.com

